Report No.: RZA1012-2086HAC

TESTING
No. L2264

ANSI C63.19

TEST REPORT

Product Name	GSM /WCDMA dual mode mobile phone
Model	W110
FCC ID	WLPW110CBW
Client	Shanghai Longcheer3g Technology Co.,Ltd.

TA Technology (Shanghai) Co., Ltd.

GENERAL SUMMARY

Product Name	GSM /WCDMA dual mode mobile phone	**Model**	W110
FCC ID	WLPW110CBW	**Report No.**	RZA1012-2086HAC
Client	Shanghai Longcheer3g Technology Co.,Ltd.		
Manufacturer	Shanghai Longcheer3g Technology Co.,Ltd.		
Reference Standard(s)	**ANSI C63.19-2007:** American National Standard Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.		
Conclusion	This portable wireless equipment has been measured in all cases requested by the relevant standards. General Judgment: **M3 (RF Emission)** (Stamp) **Date of issue: March 23rd, 2011**		
Comment	The test result only responds to the measured sample.		

Approved by______________ **Revised by**______________ **Performed by**____________

Yang Weizhong   Ling Minbao   Li Siyuan

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1. General Information

1.1. Notes of the Test Report

TA Technology (Shanghai) Co., Ltd. guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

TA Technology (Shanghai) Co., Ltd. is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

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If the electrical report is inconsistent with the printed one, it should be subject to the latter.

1.2. Testing Laboratory

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1.3. Applicant Information

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1.4. Manufacturer Information

Company:	Shanghai Longcheer3g Technology Co.,Ltd.
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City:	Shanghai
Postal Code:	201204
Country:	P.R. China
Telephone:	+86-21-64088898
Fax:	+86-21-54970816

1.5. Information of EUT

General Information

Device Type:	Portable Device		
Product Name:	GSM /WCDMA dual mode mobile phone		
IMEI:	355077010033719		
Hardware Version:	LQWM232A		
Software Version:	LQWHM01.1.0		
Antenna Type:	Internal Antenna		
Device Operating Configurations:			
Supporting Mode(s):	GSM 850/GSM 1900 (tested)		
	WCDMA Band IV (tested)		
	Bluetooth		
Test Modulation:	(GSM)GMSK; (WCDMA)QPSK		
Device Class:	B		
GPRS Multislot Class(10):	Max Number of Timeslots in Uplink	2	
	Max Number of Timeslots in Downlink	4	
	Max Total Timeslot	5	
EGPRS Multislot Class(10):	Max Number of Timeslots in Uplink	2	
	Max Number of Timeslots in Downlink	4	
	Max Total Timeslot	5	
Operating Frequency Range(s):	Mode	Tx (MHz)	Rx (MHz)
	GSM 850	824.2 ~ 848.8	869.2 ~ 893.8
	GSM 1900	1850.2 ~ 1909.8	1930.2 ~ 1989.8
	WCDMA Band IV	1712.4 ~ 1752.6	2112.4 ~ 2152.6
Test Channel: (Low - Middle - High)	128 - 190 - 251 (GSM 850) (tested) 512 - 661 - 810 (GSM 1900) (tested) 1312 - 1413 - 1513 (WCDMA Band IV) (tested)		
Power Class:	GSM 850: 4, tested with power level 5		
	GSM 1900: 1, tested with power level 0		
	WCDMA Band IV: 3, tested with power control all up bits		

Auxiliary Equipment Details

AE1:Battery

Model: BL-4C-800mAh(UL)

Manufacturer: SHENZHEN BAK BATTERY CO.,LTD.

S/N: BAK1101000123

Equipment Under Test (EUT) is a model of GSM /WCDMA dual mode mobile phone. The detail about Mobile phone and Lithium Battery is in chapter 1.5 in this report. HAC is tested for GSM 850, GSM 1900 and WCDMA Band IV. The device has an internal antenna for GSM/WCDMA Tx/Rx, and the other is BT antenna that is used for Tx/Rx.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C
Relative humidity	Min. = 0%, Max. = 80%
Ground system resistance	< 0.5 Ω
Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.	

1.7. The Total M-rating of each tested band

Mode	Rating
GSM 850	**M3**
GSM 1900	**M3**
WCDMA Band IV	**M4**

1.8. Test Date

The test is performed on March 11, 2011.

2. Test Information

2.1. Operational Conditions during Test

2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. The EUT holder is on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

2.1.2. GSM/WCDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radiofrequency Channel Number (ARFCN) is allocated to 128, 190 and 251 in the case of GSM 850, to 512, 661 and 810 in the case of GSM 1900, to 1312, 1413 and 1513 in the case of WCDMA Band IV. The EUT is commanded to operate at maximum transmitting power.Using E5515C the power lever is set to "5" of GSM 850, set to "0" of GSM 1900. Set to all "1's" for WCDMA.

2.2. HAC RF Measurements System Configuration

2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY5 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

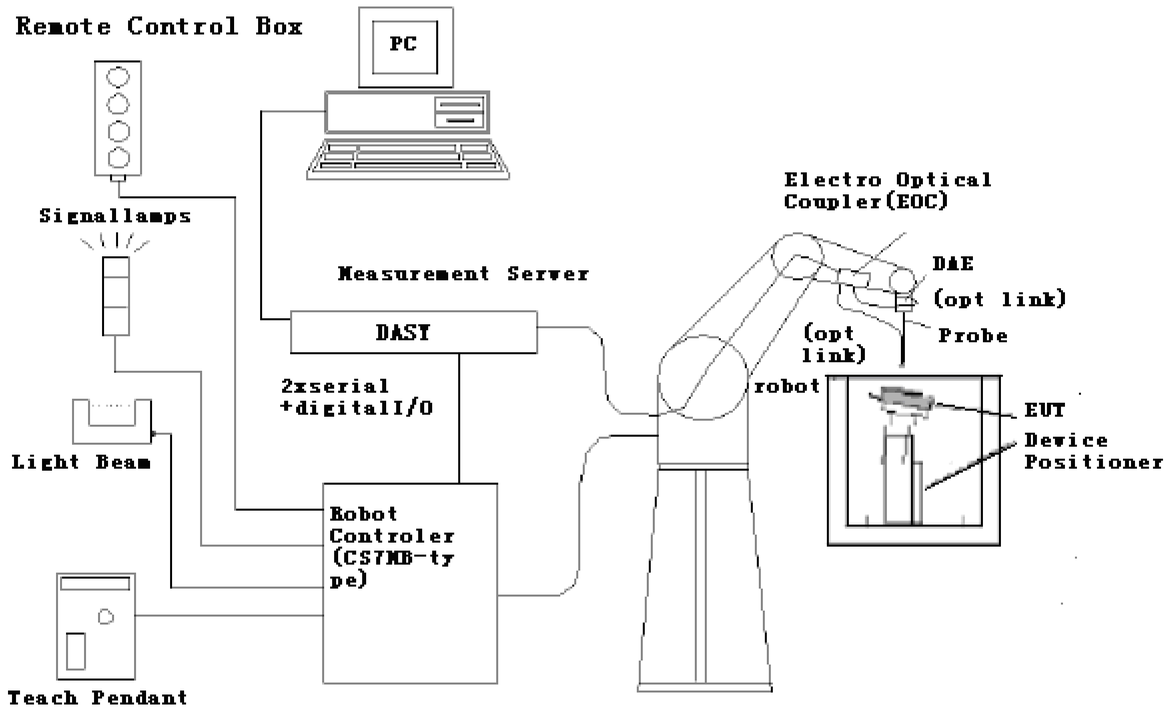


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

E-Field Probe Description

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Calibration	In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency	40 MHz to > 6 GHz (can be extended to < 20 MHz) Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm
Application	General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

Figure 2 ER3DV6 E-field Probe

H-Field Probe Description

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
Frequency	200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2); Output linearized
Directivity	± 0.2 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
E-Field Interference	< 10% at 3 GHz (for plane wave)
Dimensions	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm

Figure 3 H3DV6 H-field Probe

Application	General magnetic near-field measurements up to 3 GHz (in air or liquids) Field component measurements Surface current measurements Low interaction with the measured field

2.2.3. Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: 370 x 370 x 370 mm).

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the “user point \Height Check 0.5 mm” is 0.5mm above the center, allowing verication of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field <±0.5 dB.

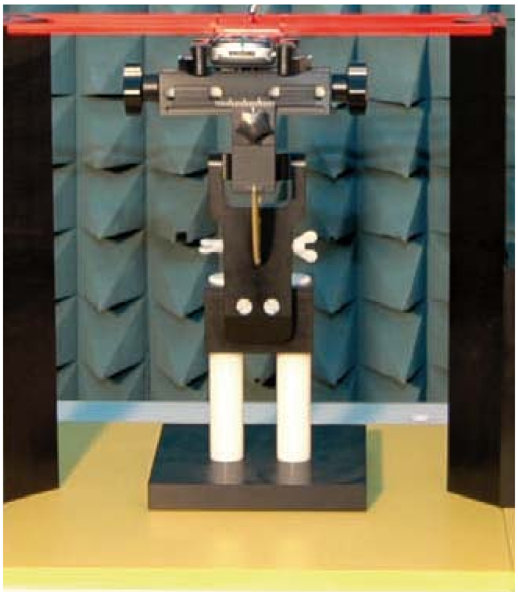


Figure 4 HAC Phantom & Device Holder

2.3. RF Test Procedures

The evaluation was performed with the following procedure:

1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
5. Record the reading.
6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.

Figure 5 WD reference and plane for RF emission measurements

2.4. System Check

Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.
The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.
The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements.
Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target refenence values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

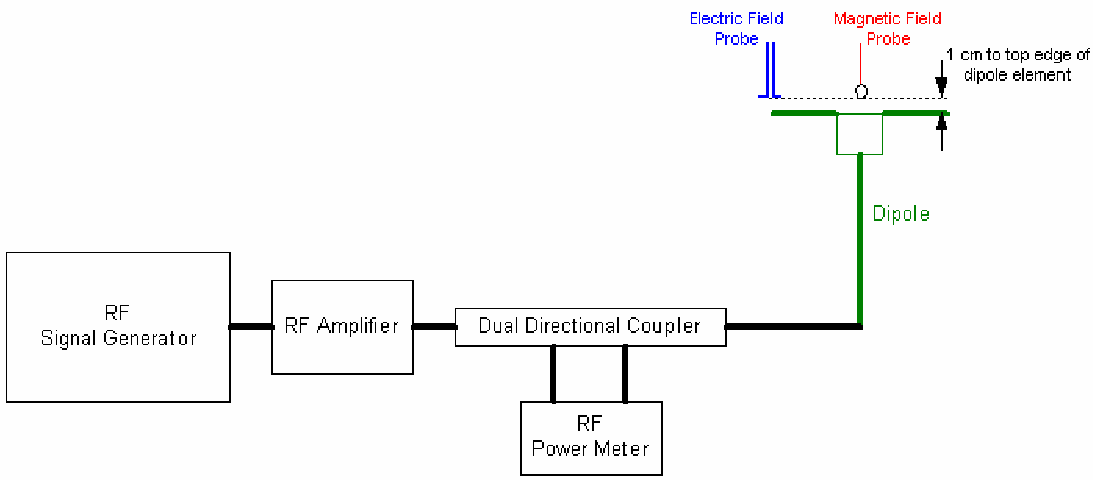


Figure 6 Dipole Validation Setup

Dipole Measurement Summary

E-Field Scan						
Mode	**Frequency (MHz)**	**Input Power (mW)**	**Measured[1] Value(V/m)**	**Target[2] Value(V/m)**	**Deviation[3] (%)**	**Test Date**
CW	835	100	149.2	158.2	5.69	March 11, 2011
CW	1880	100	131.4	140.5	6.48	March 11, 2011
F-Field Scan						
Mode	**Frequency (MHz)**	**Input Power (mW)**	**Measured Value(A/m)**	**Target Value(A/m)**	**Deviation (%)**	**Test Date**
CW	835	100	0.443	0.446	0.67	March 11, 2011
CW	1880	100	0.449	0.468	4.06	March 11, 2011

Notes: 1. please refer to the attachment for detailed measurement data and plot.
2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
3. Deviation (%) = 100 * (Target value minus Measured value) divided by Target value.

2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1).Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Modulation Factor Test Procedure

This may be done using the following procedure:

1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
6. Record the reading of the probe measurement system of the unmodulated signal.
7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod}$ ($PMF_H = H_{CW} / H_{mod}$)
8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

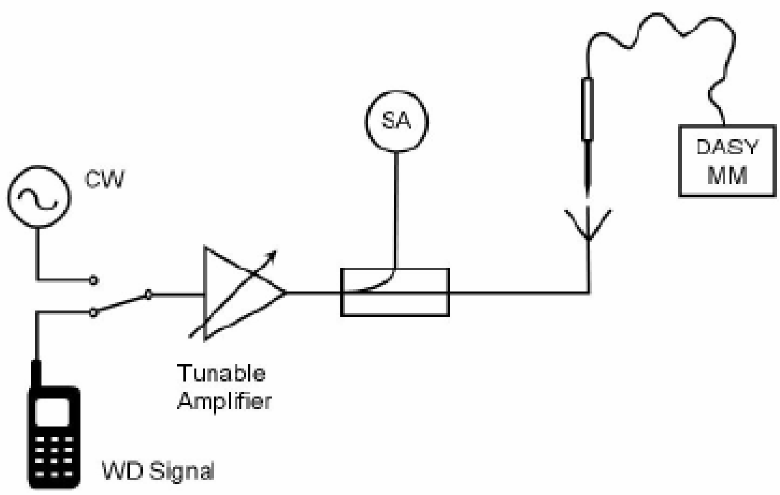


Figure 7 Probe Modulation Factor Test Setup

PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
GSM 850	2.81	2.84
GSM 1900	2.84	2.84
WCDMA Band IV	1.01	1.02

2.6. Conducted Output Power Measurement

Summary

The DUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

Conducted Power Results

GSM 850	**Conducted Power(dBm)**		
	Channel 128	Channel 190	Channel 251
Results	32.18	32.12	32.00
GSM 1900	**Conducted Power(dBm)**		
	Channel 512	Channel 661	Channel 810
Results	28.04	28.30	28.50

WCDMA Band IV		**Conducted Power (dBm)**		
		Channel 1312	Channel 1413	Channel 1513
RMC	12.2kbps RMC	22.36	22.42	22.17
	64kbps RMC	22.25	22.41	22.11
	144kbps RMC	22.32	22.38	22.08
	384kbps RMC	22.24	22.34	22.12

3. Test Results

3.1. ANSI C63.19-2007 Limits

Category		Telephone RF parameters < 960 MHz			
Near field	**AWF**	**E-field emissions**		**H-field emissions**	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m
	–5	473.2 to 841.4	V/m	1.43 to 2.54	A/m
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m
	–5	266.1 to 473.2	V/m	0.80 to 1.43	A/m
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	–5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M4/T4	0	< 199.5	V/m	< 0.60	A/m
	–5	< 149.6	V/m	< 0.45	A/m
Category		**Telephone RF parameters > 960 MHz**			
Near field	**AWF**	**E-field emissions**		**H-field emissions**	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	–5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m
	–5	84.1 to 149.6	V/m	0.25 to 0.45	A/m
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m
	–5	47.3 to 84.1	V/m	0.14 to 0.25	A/m
Category M4/T4	0	< 63.1	V/m	< 0.19	A/m
	–5	< 47.3	V/m	< 0.14	A/m

3.2. Summary Test Results

GSM 850 Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
251	848.8	207.100	0.009	M3	Figure 12
190	836.6	224.500	-0.072	M3	Figure 13
128	824.2	232.800	-0.064	M3	Figure 14
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
251	848.8	0.294	-0.011	M4	Figure 15
190	836.6	0.319	-0.070	M4	Figure 16
128	824.2	0.323	-0.027	M4	Figure 17

GSM 1900 Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
810	1909.8	77.300	0.071	M3	Figure 18
661	1880	66.500	-0.021	M3	Figure 19
512	1850.2	59.300	0.048	M3	Figure 20
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
810	1909.8	0.229	-0.010	M3	Figure 21
661	1880	0.198	0.003	M3	Figure 22
512	1850.2	0.168	0.009	M3	Figure 23

WCDMA Band IV Results

E-Field					
Channel	**Frequency (MHz)**	**Peak Field (V/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
1513	1752.6	32.100	0.000	M4	Figure 24
1413	1732.6	32.400	-0.034	M4	Figure 25
1312	1712.4	35.500	-0.122	M4	Figure 26
H-Field					
Channel	**Frequency (MHz)**	**Peak Field (A/m)**	**Power Drift (dB)**	**Rating**	**Graph Results**
1513	1752.6	0.092	-0.005	M4	Figure 27
1413	1732.6	0.091	-0.015	M4	Figure 28
1312	1712.4	0.101	0.039	M4	Figure 29

4. Measurement Uncertainty

No.	Error source	Type	Uncertainty Value (%)	Prob. Dist.	k	c_iE	c_iH	Standard Uncertainty (%) $u_i^{'}$ (%) E	Standard Uncertainty (%) $u_i^{'}$ (%) H	Degree of freedom V_{eff} or v_i
Measurement System										
1	Probe Calibration	B	5.	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	B	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Linearity	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
6	Scaling to Peak Envelope Power	B	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
7	System Detection Limit	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
8	Readout Electronics	B	0.3	N	1	1	1	0.3	0.3	∞
9	Response Time	B	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
10	Integration Time	B	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
11	RF Ambient Conditions	B	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
12	RF Reflections	B	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
13	Probe Positioner	B	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
14	Probe Positioning	A	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
15	Extra. And Interpolation	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test Sample Related										
16	Device Positioning Vertical	B	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
17	Device Positioning Lateral	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
18	Device Holder and Phantom	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞

19	Power Drift	B	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞
Phantom and Setup related										
20s	Phantom Thickness	B	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Combined standard uncertainty(%)								14.7	10.9	
Expanded uncertainty (confidence interval of 95 %)		$u_e = 2u_c$		N	k=2			29.4	21.8	

5. Main Test Instruments

No.	Name	Type	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 13, 2010	One year
02	Power sensor	Agilent N8481H	MY50350004	September 26, 2010	One year
03	Signal Generator	HP 8341B	2730A00804	September 13, 2010	One year
04	Amplifier	IXA-020	0401	No Calibration Requested	
05	BTS	E5515C	MY48360988	December 3, 2010	One year
06	E-Field Probe	ER3DV6	2428	October 20, 2009	Two years
07	H-Field Probe	H3DV6	6260	October 20, 2009	Two years
08	DAE	DAE4	871	November 18, 2010	One year
09	Validation Kit 835MHz	CD835V3	1133	April 22, 2009	Two years
10	Validation Kit 1880MHz	CD1880V3	1115	April 22, 2009	Two years

*******END OF REPORT BODY*******

ANNEX A: System Check Results

HAC_System Performance Check at 835MHz_E

DUT: Dipole 835 MHz; Type: CD835V3; SN:1133

Date/Time: 3/11/2011 5:10:32 AM

Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 149.2 V/m

Probe Modulation Factor = 1.00

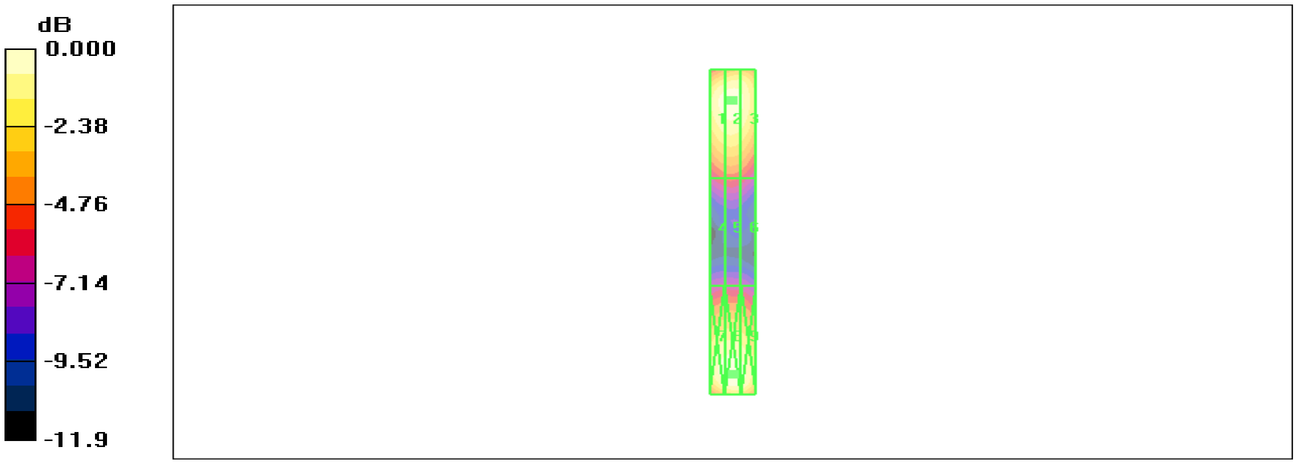
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 100.7 V/m; Power Drift = -0.066 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **147.0 M4**	Grid 2 **149.2 M4**	Grid 3 **143.9 M4**
Grid 4 **83.4 M4**	Grid 5 **85.0 M4**	Grid 6 **81.1 M4**
Grid 7 **148.8 M4**	Grid 8 **154.0 M4**	Grid 9 **148.9 M4**



0 dB = 154.0V/m

Figure 8 System Performance Check 835MHz_E

HAC_System Performance Check at 835MHz_H

DUT: Dipole 835 MHz; Type: CD835V3; SN: 1133

Date/Time: 3/11/2011 6:37:58 AM

Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.443 A/m

Probe Modulation Factor = 1.00

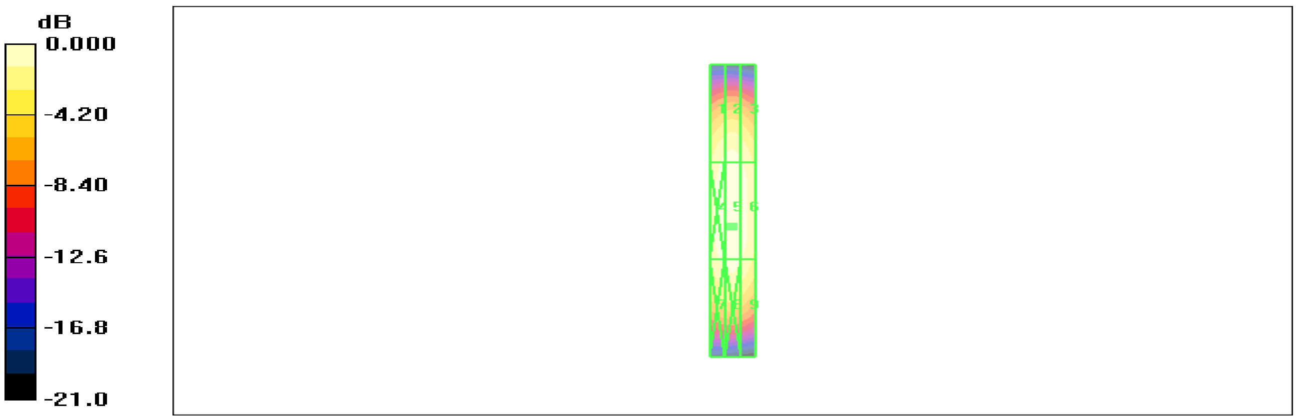
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.464 A/m; Power Drift = 0.019 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.391 M4**	Grid 2 **0.408 M4**	Grid 3 **0.384 M4**
Grid 4 **0.427 M4**	Grid 5 **0.443 M4**	Grid 6 **0.414 M4**
Grid 7 **0.397 M4**	Grid 8 **0.410 M4**	Grid 9 **0.381 M4**



0 dB = 0.443A/m

Figure 9 System Performance Check 835MHz_H

HAC_System Performance Check at 1880MHz_E

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1115

Date/Time: 3/11/2011 8:00:34 AM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 131.4 V/m

Probe Modulation Factor = 1.00

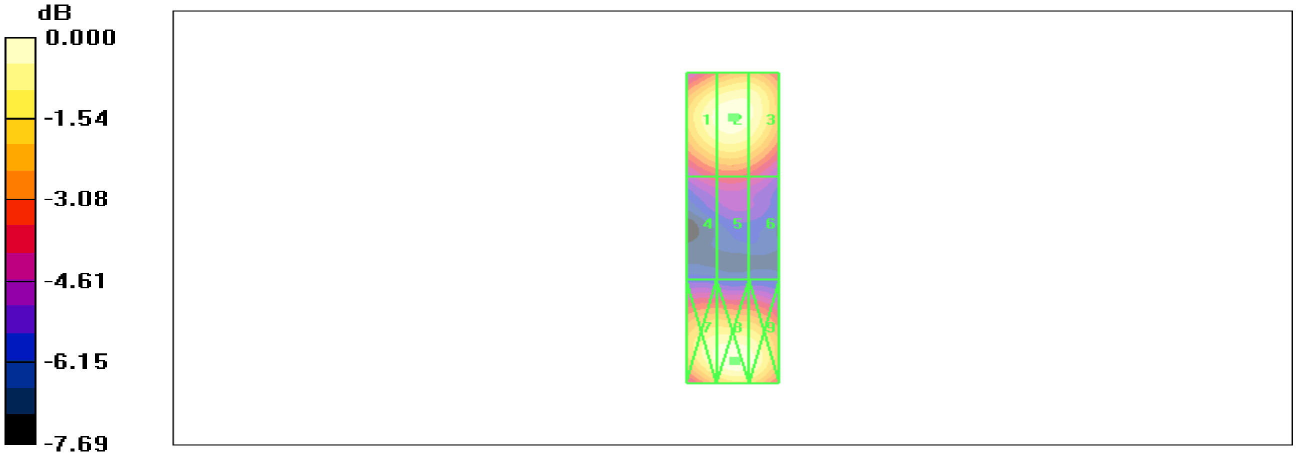
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 151.0 V/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **128.5 M2**	Grid 2 **131.4 M2**	Grid 3 **128.5 M2**
Grid 4 **87.5 M3**	Grid 5 **89.7 M3**	Grid 6 **86.2 M3**
Grid 7 **128.7 M2**	Grid 8 **134.0 M2**	Grid 9 **130.3 M2**



0 dB = 134.0V/m

Figure 10 System Performance Check 1880MHz_E

HAC_System Performance Check at 1880MHz_H

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1115

Date/Time: 3/11/2011 9:21:22 AM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.449 A/m

Probe Modulation Factor = 1.00

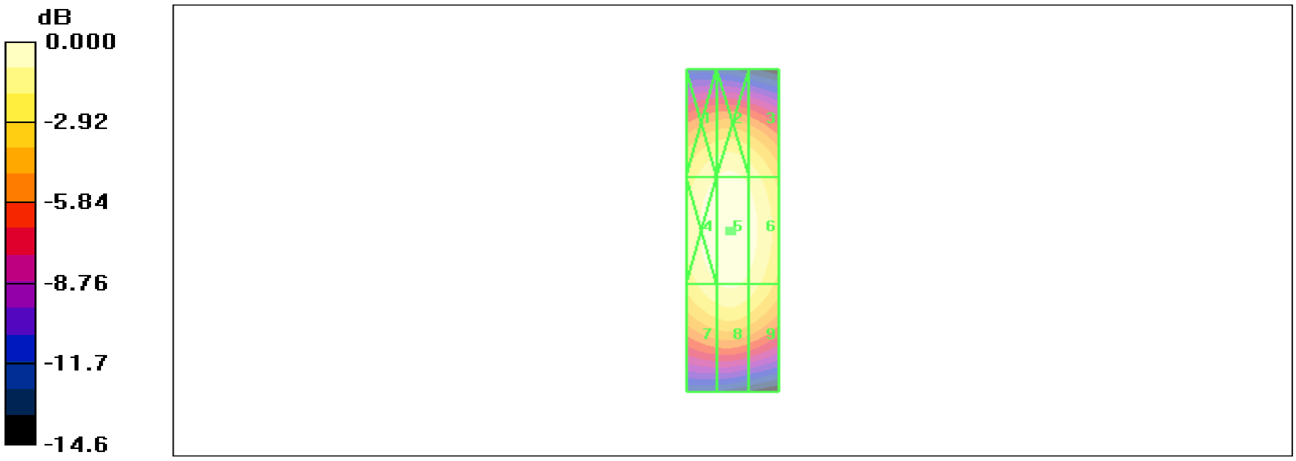
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.472 A/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.400 M2**	Grid 2 **0.413 M2**	Grid 3 **0.387 M2**
Grid 4 **0.435 M2**	Grid 5 **0.449 M2**	Grid 6 **0.422 M2**
Grid 7 **0.397 M2**	Grid 8 **0.410 M2**	Grid 9 **0.384 M2**



0 dB = 0.449A/m

Figure 11 System Performance Check 1880MHz_H

ANNEX B: Graph Results

HAC RF E-Field GSM 850 High

Date/Time: 3/11/2011 12:38:22 PM

Communication System: GSM850; Frequency: 848.8 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 207.1 V/m

Probe Modulation Factor = 2.81

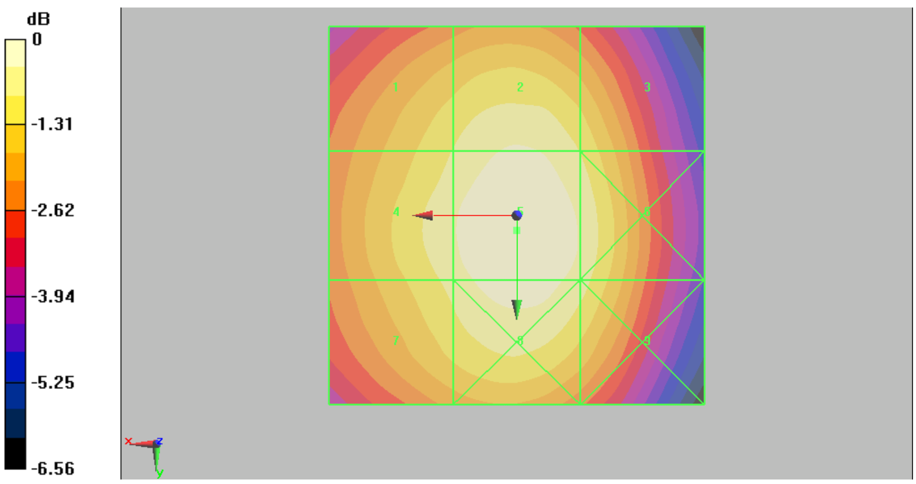
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 100.3 V/m; Power Drift = 0.009 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **187.7 M3**	Grid 2 **198.1 M3**	Grid 3 **186.8 M3**
Grid 4 **196.0 M3**	Grid 5 **207.1 M3**	Grid 6 **196.0 M3**
Grid 7 **191.1 M3**	Grid 8 **202.5 M3**	Grid 9 **191.8 M3**



0 dB = 207.1V/m

Figure 12 HAC RF E-Field GSM 850 Channel 251

HAC RF E-Field GSM 850 Middle

Date/Time: 3/11/2011 12:27:48 PM

Communication System: GSM850; Frequency: 836.6 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 224.5 V/m

Probe Modulation Factor = 2.81

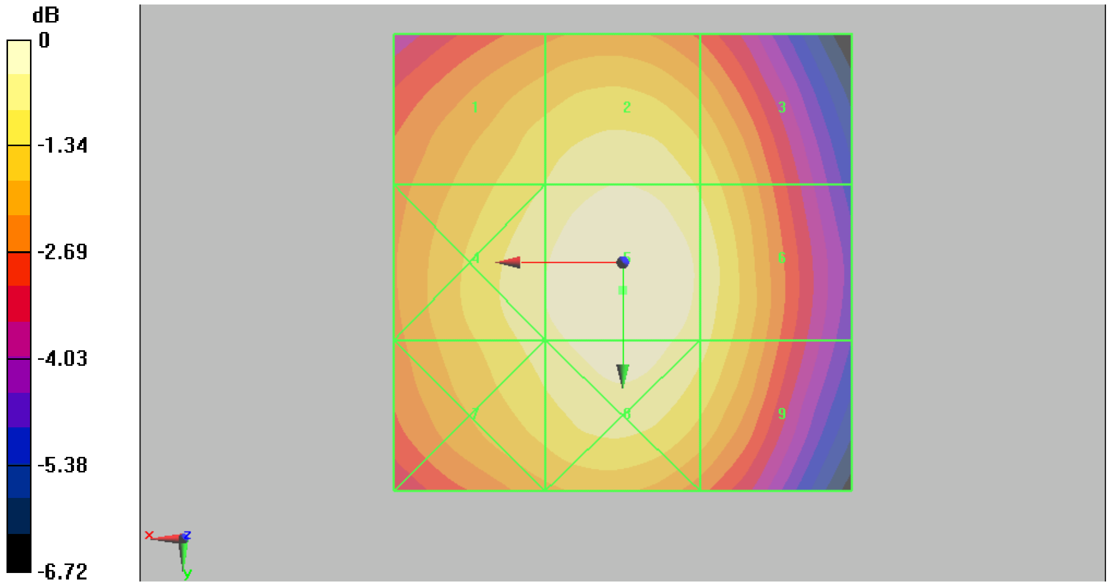
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 109.5 V/m; Power Drift = -0.072 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **203.0 M3**	Grid 2 **213.4 M3**	Grid 3 **200.8 M3**
Grid 4 **213.4 M3**	Grid 5 **224.5 M3**	Grid 6 **211.2 M3**
Grid 7 **208.7 M3**	Grid 8 **219.6 M3**	Grid 9 **206.2 M3**



0 dB = 224.5V/m

Figure 13 HAC RF E-Field GSM 850 Channel 190

HAC RF E-Field GSM 850 Low

Date/Time: 3/11/2011 12:33:06 PM

Communication System: GSM850; Frequency: 824.2 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 232.8 V/m

Probe Modulation Factor = 2.81

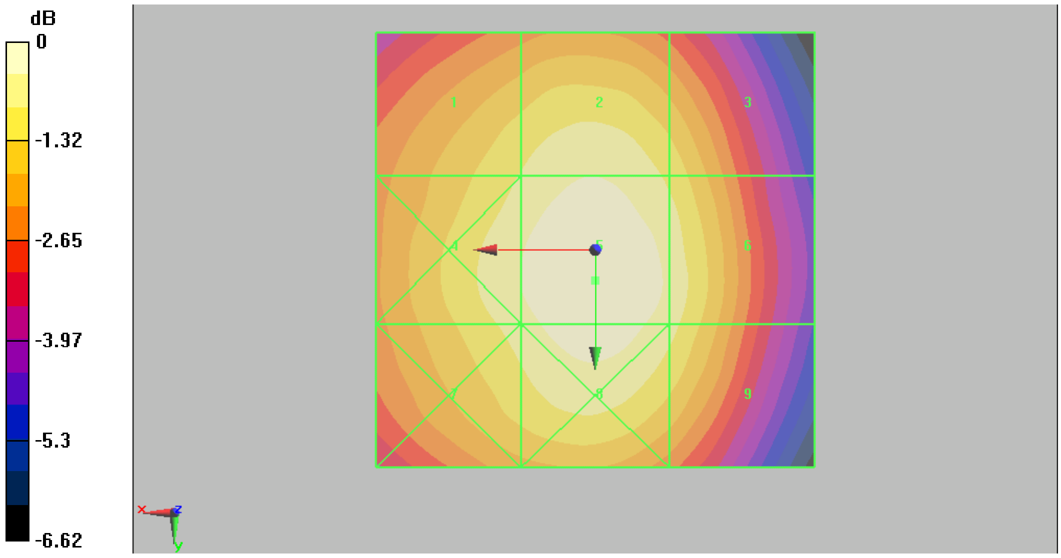
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 113.3 V/m; Power Drift = -0.064 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **211.1 M3**	Grid 2 **221.3 M3**	Grid 3 **208.0 M3**
Grid 4 **221.5 M3**	Grid 5 **232.8 M3**	Grid 6 **219.0 M3**
Grid 7 **216.3 M3**	Grid 8 **227.7 M3**	Grid 9 **214.4 M3**



0 dB = 232.8V/m

Figure 14 HAC RF E-Field GSM 850 Channel 128

HAC RF H-Field GSM 850 High

Date/Time: 3/11/2011 11:34:40 AM

Communication System: GSM850; Frequency: 848.8 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.294 A/m

Probe Modulation Factor = 2.84

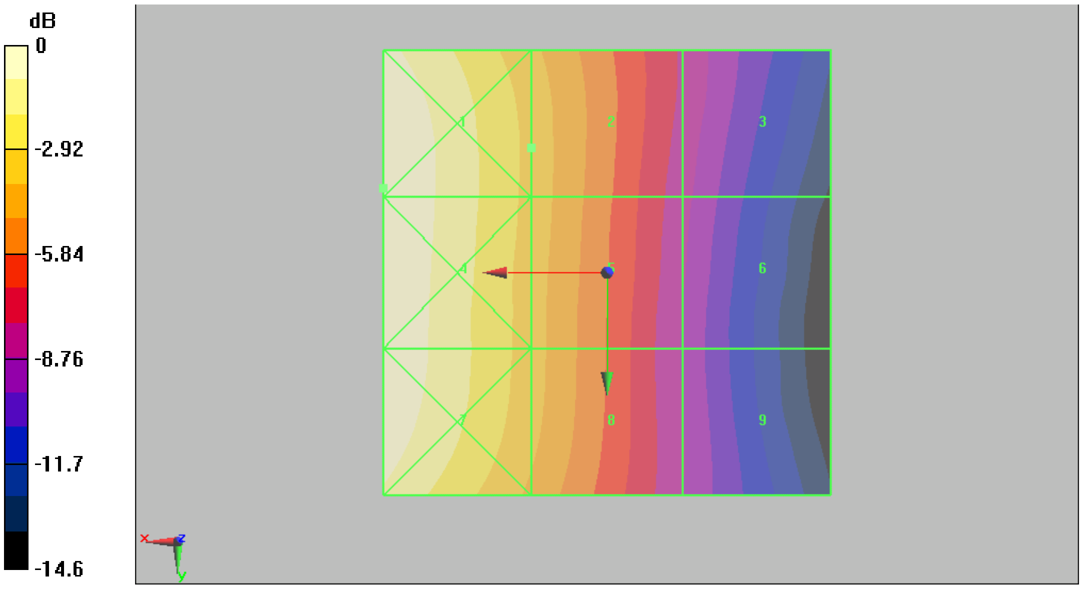
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.082 A/m; Power Drift = -0.011 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.426 M4**	Grid 2 **0.294 M4**	Grid 3 **0.171 M4**
Grid 4 **0.426 M4**	Grid 5 **0.293 M4**	Grid 6 **0.162 M4**
Grid 7 **0.418 M4**	Grid 8 **0.287 M4**	Grid 9 **0.157 M4**



0 dB = 0.426A/m

Figure 15 HAC RF H-Field GSM 850Channel 251

HAC RF H-Field GSM 850 Middle

Date/Time: 3/11/2011 11:28:57 AM

Communication System: GSM850; Frequency: 836.6 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.319 A/m

Probe Modulation Factor = 2.84

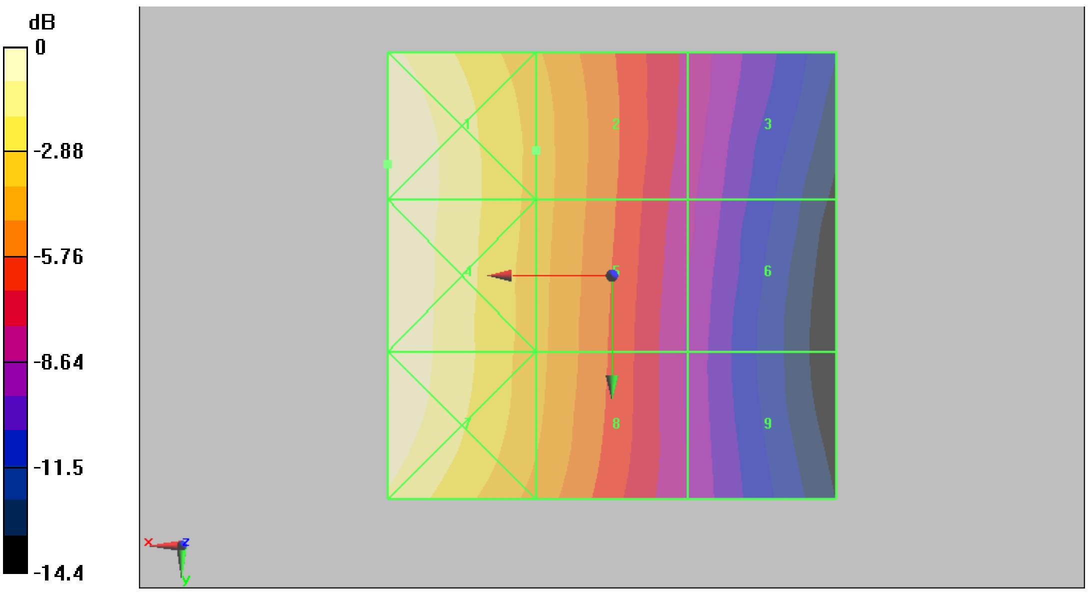
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.089 A/m; Power Drift = -0.070 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.463 M3**	Grid 2 **0.319 M4**	Grid 3 **0.187 M4**
Grid 4 **0.463 M3**	Grid 5 **0.318 M4**	Grid 6 **0.178 M4**
Grid 7 **0.456 M3**	Grid 8 **0.310 M4**	Grid 9 **0.170 M4**



0 dB = 0.463A/m

Figure 16 HAC RF H-Field GSM 850 Channel 190

HAC RF H-Field GSM 850 Low

Date/Time: 3/11/2011 11:40:00 AM

Communication System: GSM850; Frequency: 824.2 MHz;Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.323 A/m

Probe Modulation Factor = 2.84

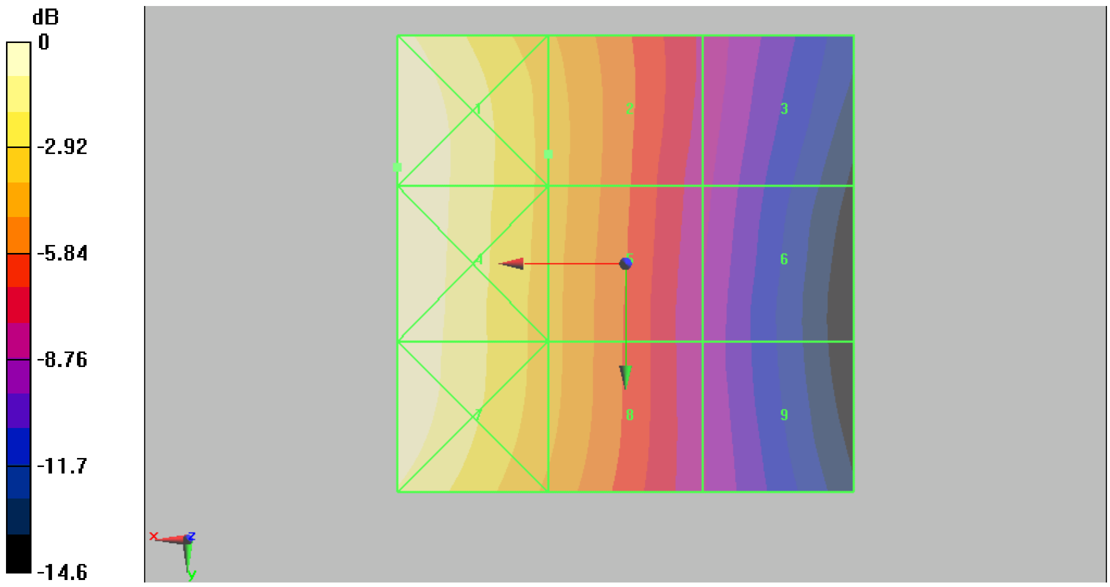
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.090 A/m; Power Drift = -0.027 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.470 M3**	Grid 2 **0.323 M4**	Grid 3 **0.188 M4**
Grid 4 **0.469 M3**	Grid 5 **0.322 M4**	Grid 6 **0.179 M4**
Grid 7 **0.463 M3**	Grid 8 **0.316 M4**	Grid 9 **0.174 M4**



0 dB = 0.470A/m

Figure 17 HAC RF H-Field GSM 850 Channel 128

HAC RF E-Field GSM 1900 High

Date/Time: 3/11/2011 12:55:49 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 77.3 V/m

Probe Modulation Factor = 2.84

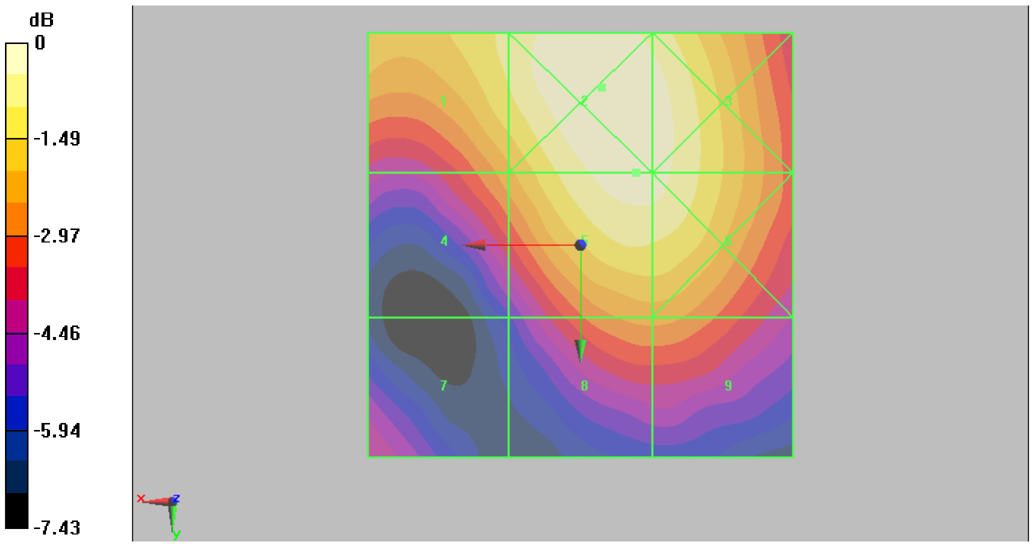
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.7 V/m; Power Drift = 0.071 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **72.6 M3**	Grid 2 **79.8 M3**	Grid 3 **77.7 M3**
Grid 4 **62.4 M3**	Grid 5 **77.3 M3**	Grid 6 **76.8 M3**
Grid 7 **50.3 M3**	Grid 8 **61.4 M3**	Grid 9 **61.4 M3**



0 dB = 79.8V/m

Figure 18 HAC RF E-Field GSM 1900 Channel 810

HAC RF E-Field GSM 1900 Middle

Date/Time: 3/11/2011 12:44:50 PM

Communication System: PCS 1900; Frequency: 1880 MHz;Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 66.5 V/m

Probe Modulation Factor = 2.84

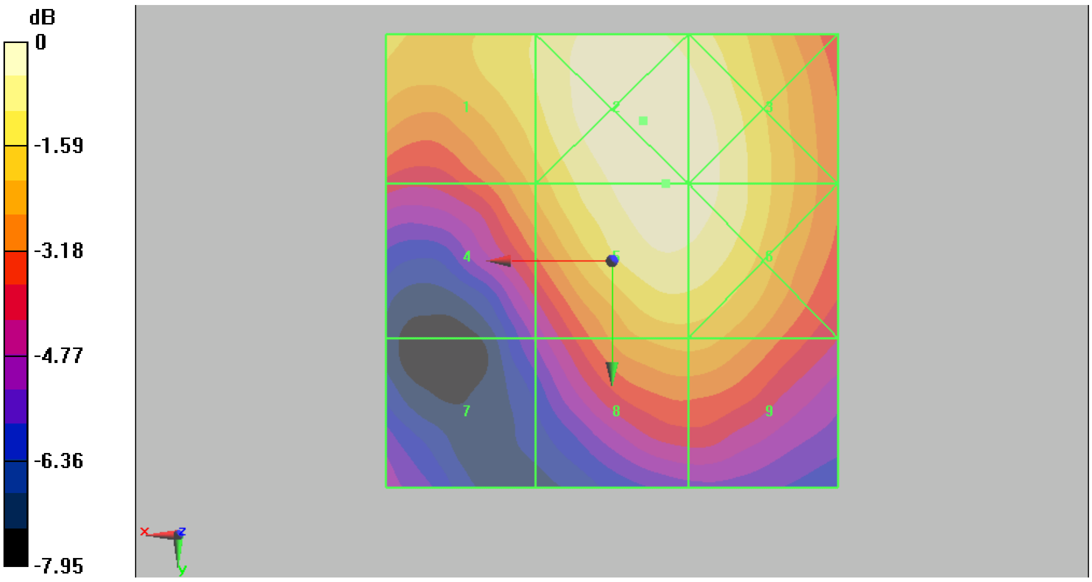
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 27.3 V/m; Power Drift = -0.021 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **60.3 M3**	Grid 2 **67.5 M3**	Grid 3 **66.3 M3**
Grid 4 **54 M3**	Grid 5 **66.5 M3**	Grid 6 **66 M3**
Grid 7 **37.9 M4**	Grid 8 **54.5 M3**	Grid 9 **54.5 M3**



0 dB = 67.5V/m

Figure 19 HAC RF E-Field GSM 1900 Channel 661

HAC RF E-Field GSM 1900 Low

Date/Time: 3/11/2011 12:50:29 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 59.3 V/m

Probe Modulation Factor = 2.84

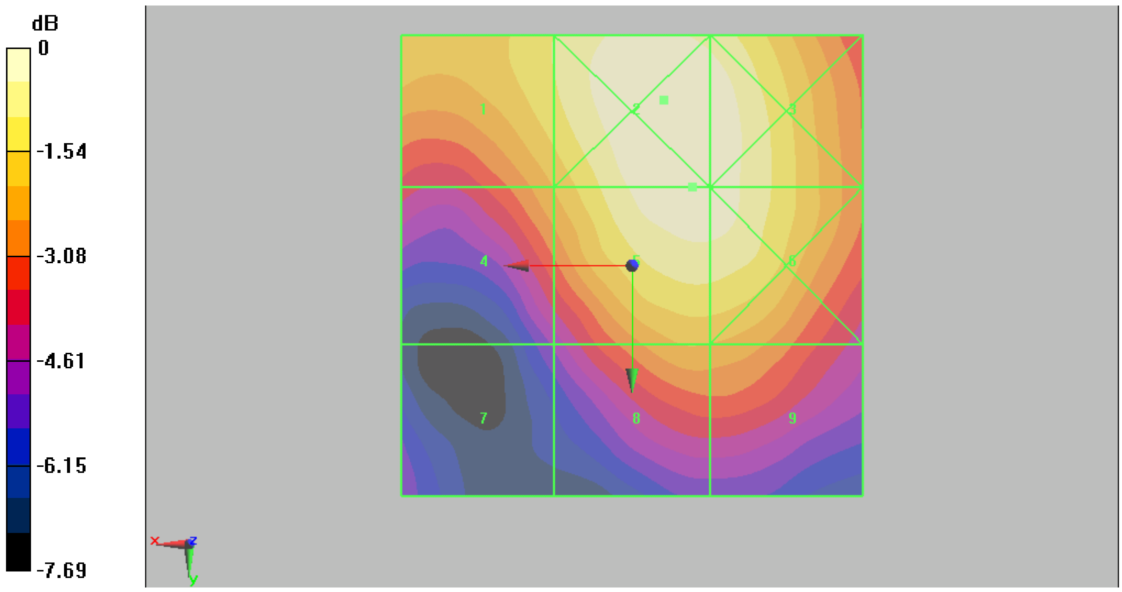
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 24.2 V/m; Power Drift = 0.048 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **54.2 M3**	Grid 2 **60.8 M3**	Grid 3 **59.8 M3**
Grid 4 **48.2 M3**	Grid 5 **59.3 M3**	Grid 6 **59.1 M3**
Grid 7 **34.3 M4**	Grid 8 **48.3 M3**	Grid 9 **48 M3**



0 dB = 60.8V/m

Figure 20 HAC RF E-Field GSM 1900 Channel 512

HAC RF H-Field GSM 1900 High

Date/Time: 3/11/2011 11:10:47 AM

Communication System: PCS 1900; Frequency: 1909.8 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.229 A/m

Probe Modulation Factor = 2.84

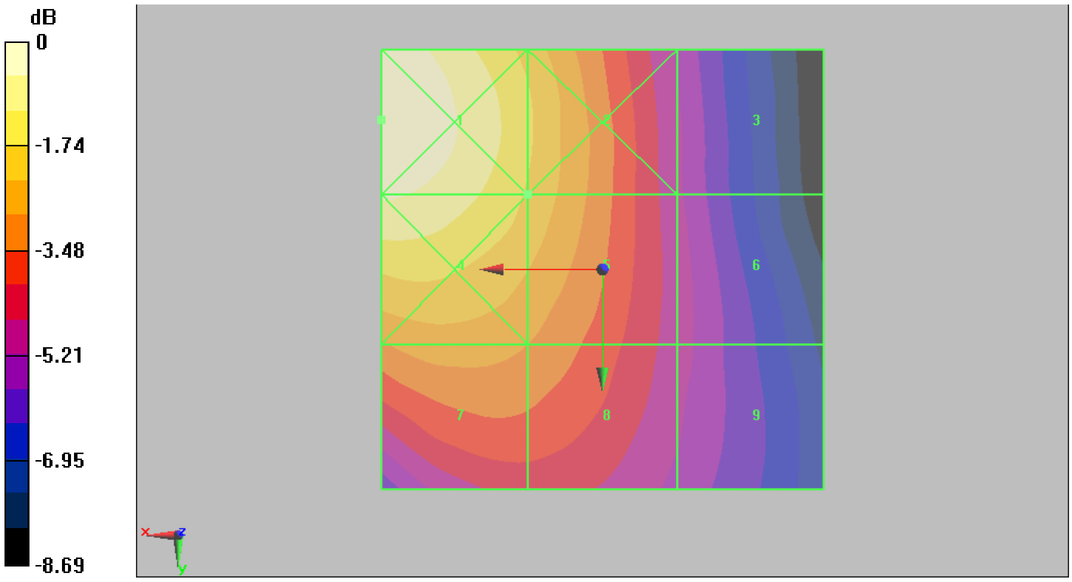
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.074 A/m; Power Drift = -0.010 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.282 M2**	Grid 2 **0.234 M3**	Grid 3 **0.158 M3**
Grid 4 **0.266 M2**	Grid 5 **0.229 M3**	Grid 6 **0.161 M3**
Grid 7 **0.210 M3**	Grid 8 **0.202 M3**	Grid 9 **0.160 M3**



0 dB = 0.282A/m

Figure 21 HAC RF H-Field GSM 1900 Channel 810

HAC RF H-Field GSM 1900 Middle

Date/Time: 3/11/2011 11:16:37 AM

Communication System: PCS 1900; Frequency: 1880 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.198 A/m

Probe Modulation Factor = 2.84

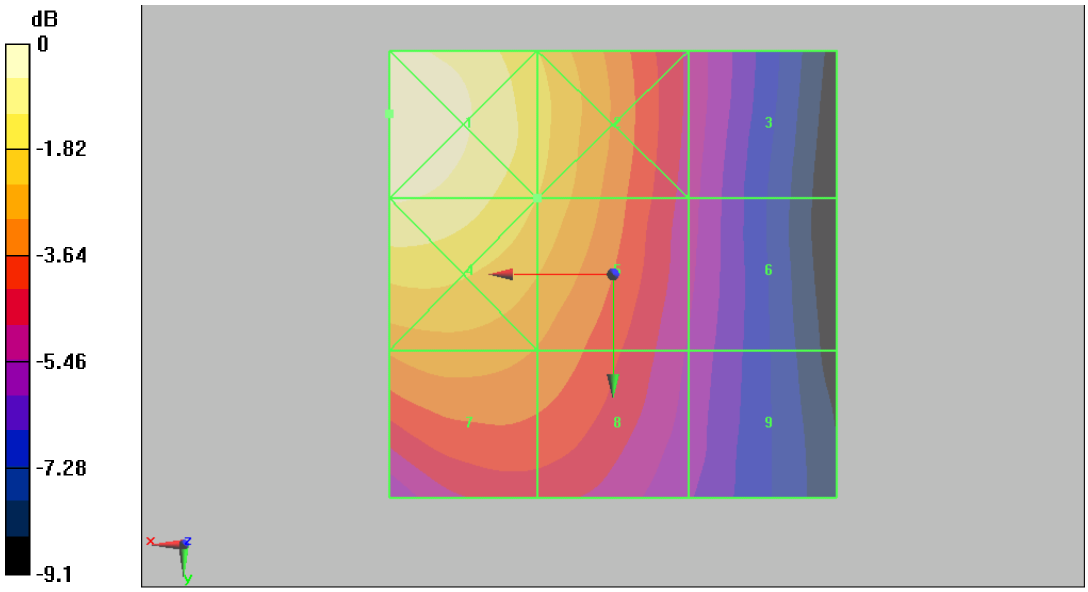
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.061 A/m; Power Drift = 0.003 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.244 M3**	Grid 2 **0.204 M3**	Grid 3 **0.138 M4**
Grid 4 **0.229 M3**	Grid 5 **0.198 M3**	Grid 6 **0.135 M4**
Grid 7 **0.180 M3**	Grid 8 **0.171 M3**	Grid 9 **0.129 M4**



0 dB = 0.244A/m

Figure 22 HAC RF H-Field GSM 1900 Channel 661

HAC RF H-Field GSM 1900 Low

Date/Time: 3/11/2011 11:22:11 AM

Communication System: PCS 1900; Frequency: 1850.2 MHz;Duty Cycle: 1:8.3

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.168 A/m

Probe Modulation Factor = 2.84

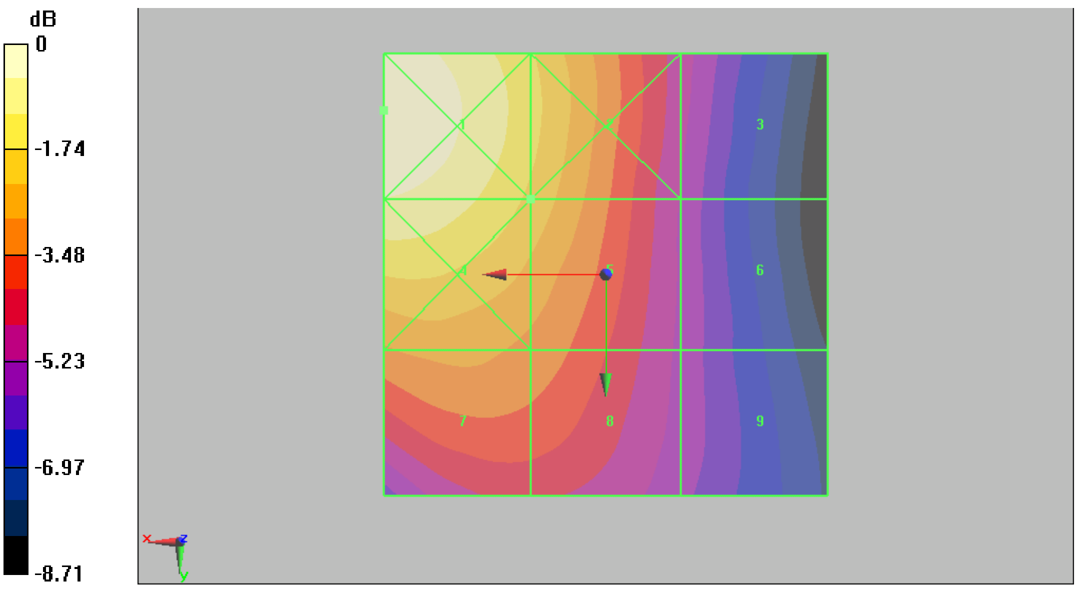
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.052 A/m; Power Drift = 0.009 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.208 M3**	Grid 2 **0.175 M3**	Grid 3 **0.118 M4**
Grid 4 **0.194 M3**	Grid 5 **0.168 M3**	Grid 6 **0.114 M4**
Grid 7 **0.152 M3**	Grid 8 **0.146 M3**	Grid 9 **0.112 M4**



0 dB = 0.208A/m

Figure 23 HAC RF H-Field GSM 1900 Channel 512

HAC RF E-Field WCDMA Band IV High

Date/Time: 3/11/2011 2:13:01 PM

Communication System: WCDMA Band IV; Frequency: 1752.6 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 32.1 V/m

Probe Modulation Factor = 1.01

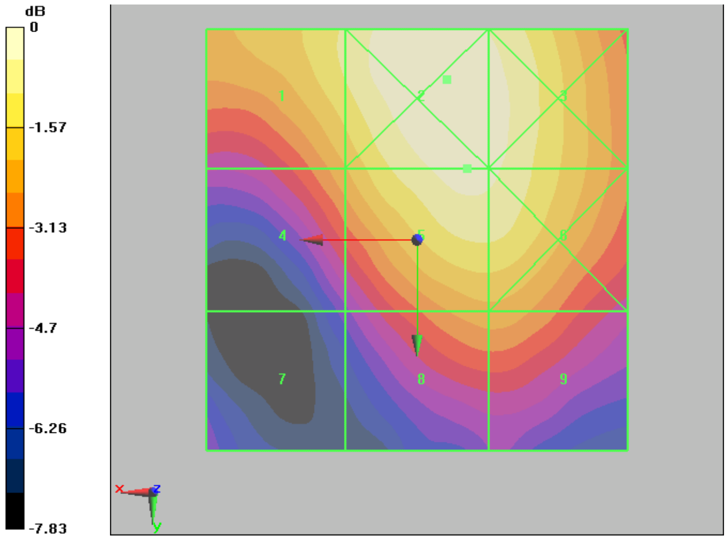
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.6 V/m; Power Drift = -0.000 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **30 M4**	Grid 2 **33.3 M4**	Grid 3 **32.3 M4**
Grid 4 **26.1 M4**	Grid 5 **32.1 M4**	Grid 6 **31.8 M4**
Grid 7 **18.2 M4**	Grid 8 **25.7 M4**	Grid 9 **25.7 M4**



0 dB = 33.3V/m

Figure 24 HAC RF E-Field WCDMA Band IV Channel 1513

HAC RF E-Field WCDMA Band IV Middle

Date/Time: 3/11/2011 2:07:42 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1000 kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 32.4 V/m

Probe Modulation Factor = 1.01

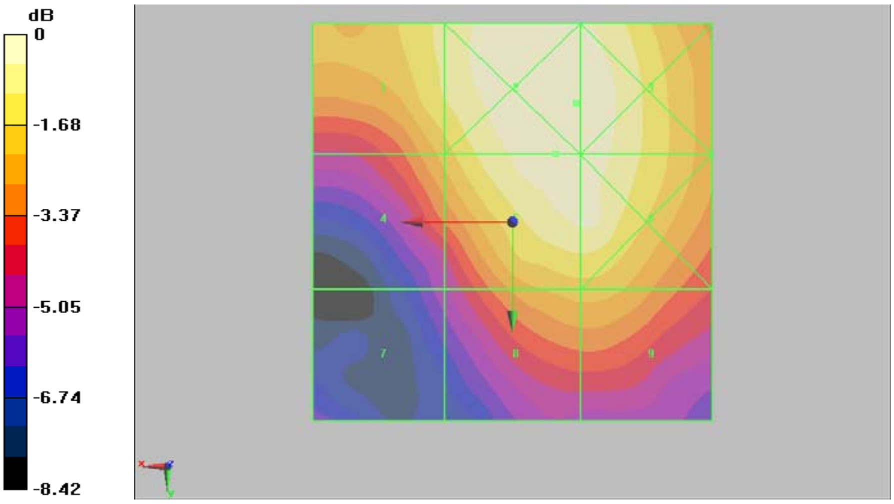
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.8 V/m; Power Drift = -0.034 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **29.6 M4**	Grid 2 **32.9 M4**	Grid 3 **32.9 M4**
Grid 4 **26.2 M4**	Grid 5 **32.4 M4**	Grid 6 **32.1 M4**
Grid 7 **18.2 M4**	Grid 8 **26.3 M4**	Grid 9 **26.3 M4**



0 dB = 32.9V/m

Figure 25 HAC RF E-Field WCDMA Band IV Channel 1413

HAC RF E-Field WCDMA Band IV Low

Date/Time: 3/11/2011 2:18:32 PM

Communication System: WCDMA Band IV; Frequency: 1712.4 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 35.5 V/m

Probe Modulation Factor = 1.01

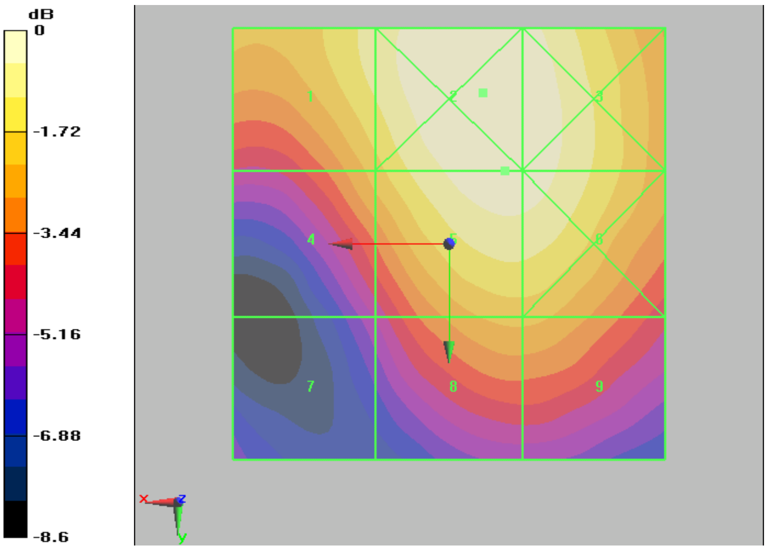
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 39.9 V/m; Power Drift = -0.122 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **32.8 M4**	Grid 2 **36.7 M4**	Grid 3 **36 M4**
Grid 4 **28.9 M4**	Grid 5 **35.5 M4**	Grid 6 **35.3 M4**
Grid 7 **20.3 M4**	Grid 8 **28.5 M4**	Grid 9 **28.5 M4**



0 dB = 36.7V/m

Figure 26 HAC RF E-Field WCDMA Band IV Channel 1312

HAC RF H-Field WCDMA Band IV High

Date/Time: 3/11/2011 2:35:15 PM

Communication System: WCDMA Band IV; Frequency: 1752.6 MHz;Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ε_r = 1; ρ = 1 kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: TCoil Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.092 A/m

Probe Modulation Factor = 1.02

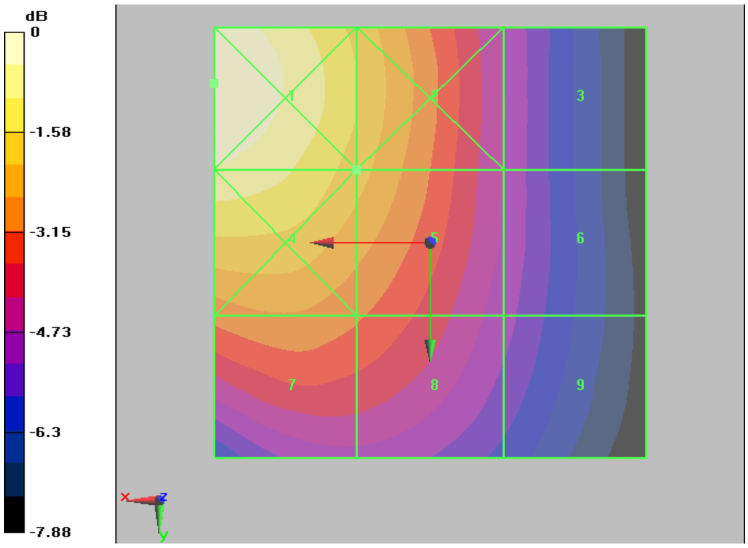
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.081 A/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.114 M4**	Grid 2 **0.095 M4**	Grid 3 **0.067 M4**
Grid 4 **0.107 M4**	Grid 5 **0.092 M4**	Grid 6 **0.066 M4**
Grid 7 **0.084 M4**	Grid 8 **0.080 M4**	Grid 9 **0.064 M4**



0 dB = 0.114A/m

Figure 27 HAC RF H-Field WCDMA Band IV Channel 1513

HAC RF H-Field WCDMA Band IV Middle

Date/Time: 3/11/2011 2:40:43 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: TCoil Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.091 A/m

Probe Modulation Factor = 1.02

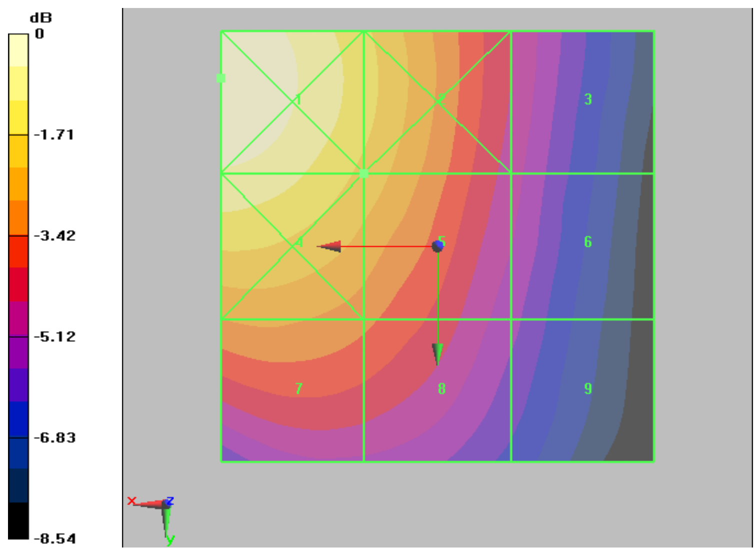
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.079 A/m; Power Drift = -0.015 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.113 M4**	Grid 2 **0.096 M4**	Grid 3 **0.067 M4**
Grid 4 **0.105 M4**	Grid 5 **0.091 M4**	Grid 6 **0.065 M4**
Grid 7 **0.083 M4**	Grid 8 **0.078 M4**	Grid 9 **0.060 M4**



0 dB = 0.113A/m

Figure 28 HAC RF H-Field WCDMA Band IV Channel 1413

HAC RF H-Field WCDMA Band IV Low

Date/Time: 3/11/2011 2:29:51 PM

Communication System: WCDMA Band IV; Frequency: 1712.4 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3

Ambient Temperature:22.3 ℃

Phantom section: TCoil Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.101 A/m

Probe Modulation Factor = 1.02

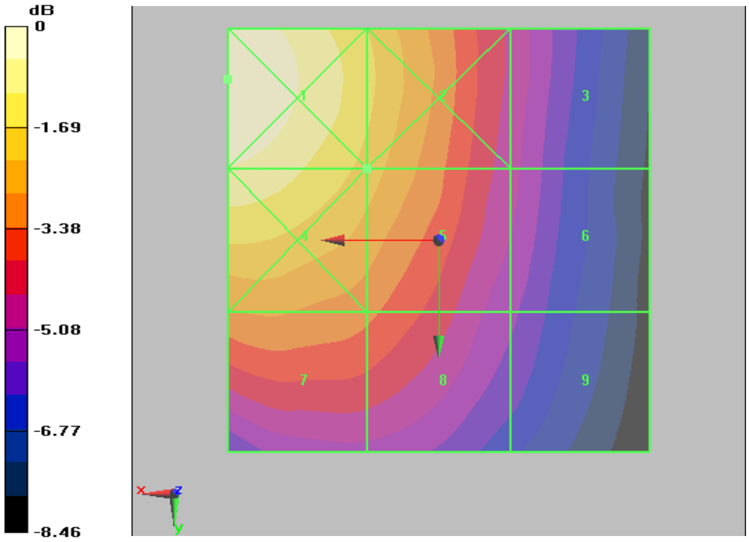
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.087 A/m; Power Drift = 0.039 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.126 M4**	Grid 2 **0.106 M4**	Grid 3 **0.074 M4**
Grid 4 **0.118 M4**	Grid 5 **0.101 M4**	Grid 6 **0.072 M4**
Grid 7 **0.092 M4**	Grid 8 **0.087 M4**	Grid 9 **0.067 M4**



0 dB = 0.126A/m

Figure 29 HAC RF H-Field WCDMA Band IV Channel 1312

ANNEX C: E-Probe Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client TMC

Certificate No: ER3-2428_Oct09

CALIBRATION CERTIFICATE

Object: ER3DV6 - SN:2428

Calibration procedure(s): QA CAL-02.v5 and QA CAL-25.v2
Calibration procedure for E-field probes optimized for close near field evaluations in air

Calibration date: October 20, 2009

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe ER3DV6	SN: 2328	3-Oct-09 (No. ER3-2328_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

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Calibration Laboratory of
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Zeughausstrasse 43, 8004 Zurich, Switzerland

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S Swiss Calibration Service

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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *NORM(f)x,y,z = NORMx,y,z * frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *Ax,y,z; Bx,y,z; Cx,y,z* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORMx* (no uncertainty required).

Probe ER3DV6

SN:2428

Manufactured:	September 11, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

DASY - Parameters of Probe: ER3DV6 SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.52	1.59	1.86	± 10.1%
DCP (mV)[A]	91.5	93.0	98.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW		X	0.00	0.00	1.00	300	± 1.5%
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

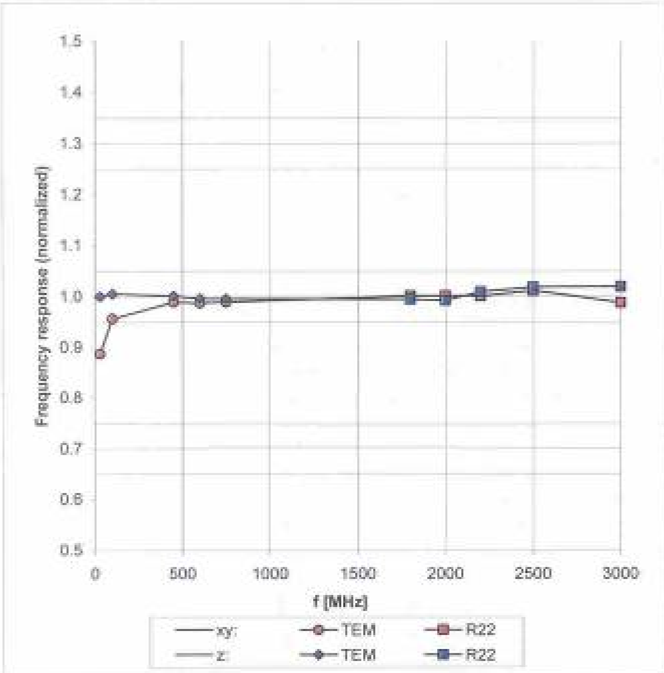
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[A] numerical linearization parameter: uncertainty not required

ER3DV6 SN:2428 October 20, 2009

Frequency Response of E-Field

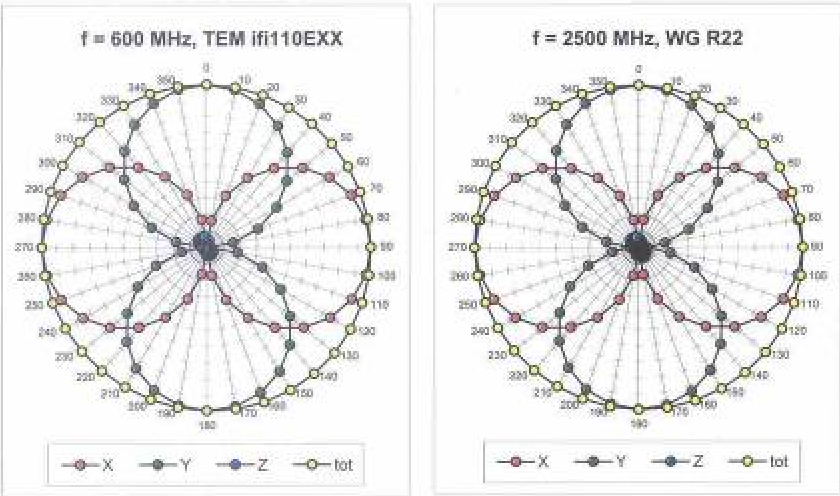
(TEM-Cell:ifi110 EXX, Waveguide R22)



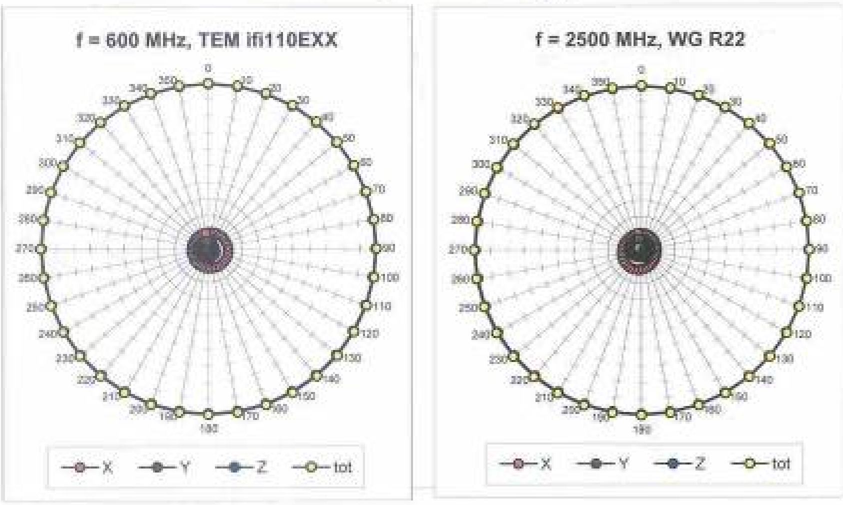
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

ER3DV6 SN:2428 October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 0°$

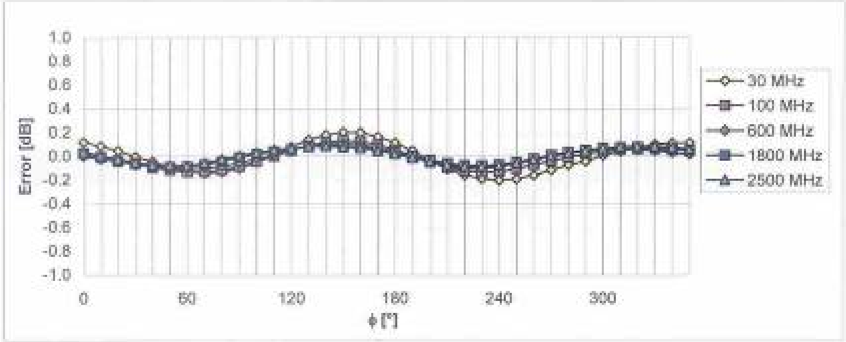


Receiving Pattern (ϕ), $\vartheta = 90°$



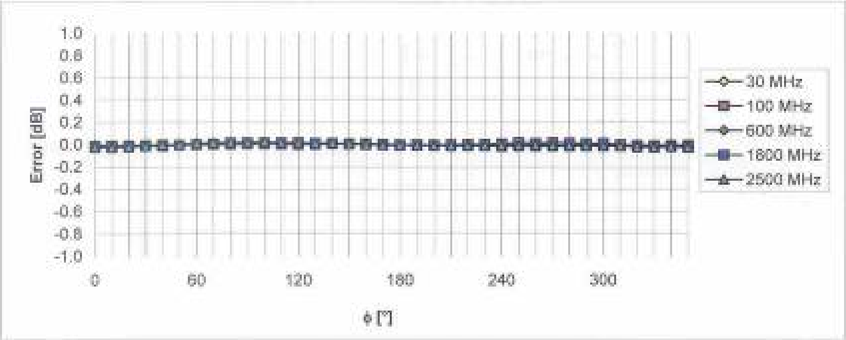
ER3DV6 SN:2428 October 20, 2009

Receiving Pattern (ϕ), ϑ = 0°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

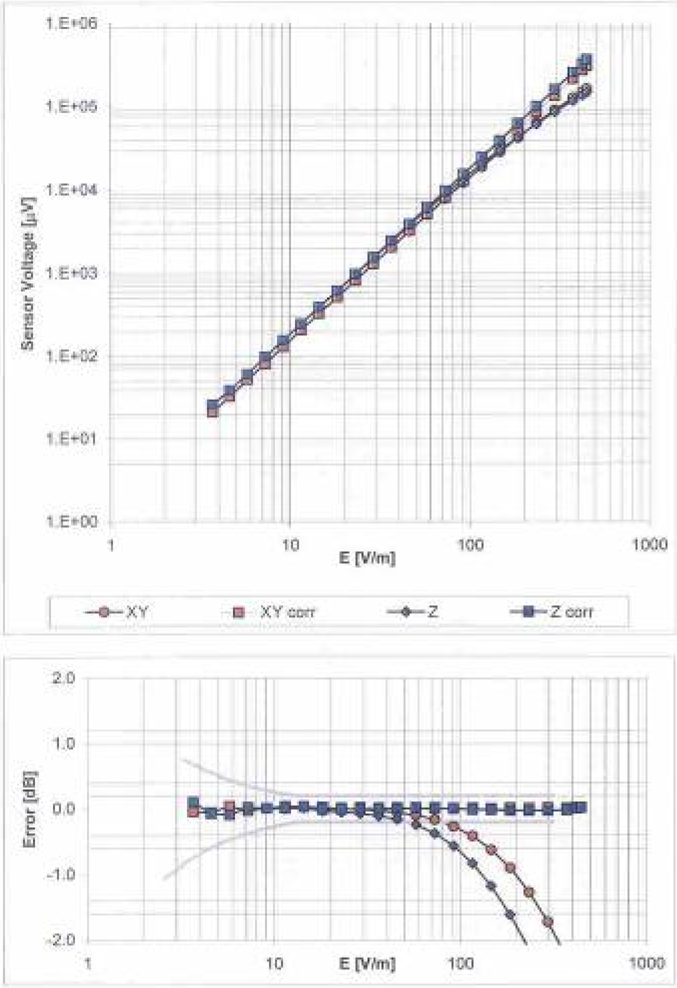
Receiving Pattern (ϕ), ϑ = 90°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Dynamic Range f(E-field)

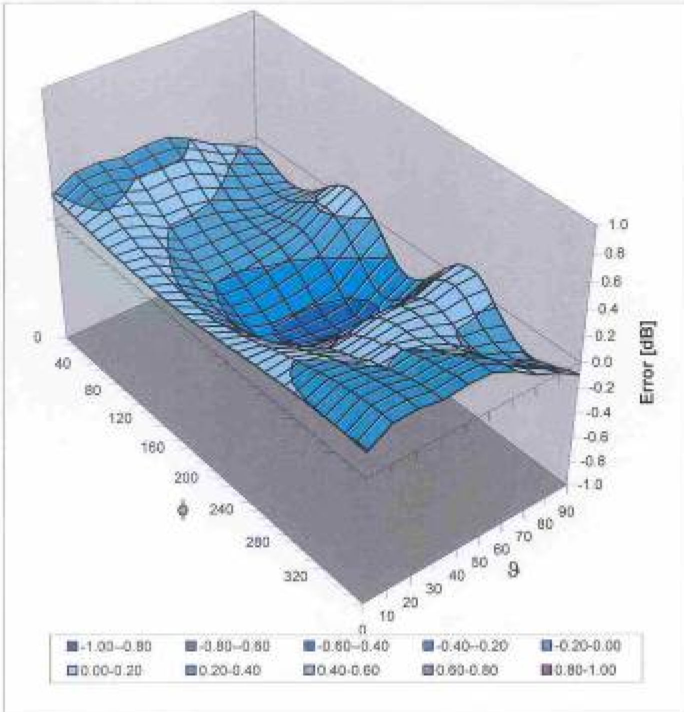
(Waveguide R22, f = 1800 MHz)



Uncertainty of Linearity Assessment: ± 0.6% (k=2)

ER3DV6 SN:2428 October 20, 2009

Deviation from Isotropy in Air
Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

ER3DV6 SN:2428 October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-218.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8.0 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

ANNEX D: H-Probe Calibration Certificate

Calibration Laboratory of
Schmid & Partner
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Zeughausstrasse 43, 8004 Zurich, Switzerland

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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TMC**

Certificate No: **H3-6260_Oct09**

CALIBRATION CERTIFICATE

Object: H3DV6 - SN:6260

Calibration procedure(s): QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field evaluations in air

Calibration date: October 20, 2009

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
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Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe H3DV6	SN: 6182	3-Oct-09 (No. H3-6182_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	M. Fehr
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Zeughausstrasse 43, 8004 Zurich, Switzerland

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Accreditation No.: **SCS 108**

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *X,Y,Z(f)_a0a1a2= X,Y,Z_a0a1a2* frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *Ax,y,z; Bx,y,z; Cx,y,z* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *X_a0a1a2* (no uncertainty required).

Probe H3DV6

SN:6260

Manufactured:	September 7, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

H3DV6 SN:6260 October 20, 2009

DASY - Parameters of Probe: H3DV6 SN:6260

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(μV))	a0	2.47E-3	2.49E-3	2.95E-3	± 10.1%
Norm (A/m / √(μV))	a1	-2.97E-5	5.62E-6	-4.47E-5	± 10.1%
Norm (A/m / √(μV))	a2	4.84E-5	4.36E-5	6.01E-5	± 10.1%
DCP (mV)[A]		84.5	90.3	83.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	300	± 1.5%
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

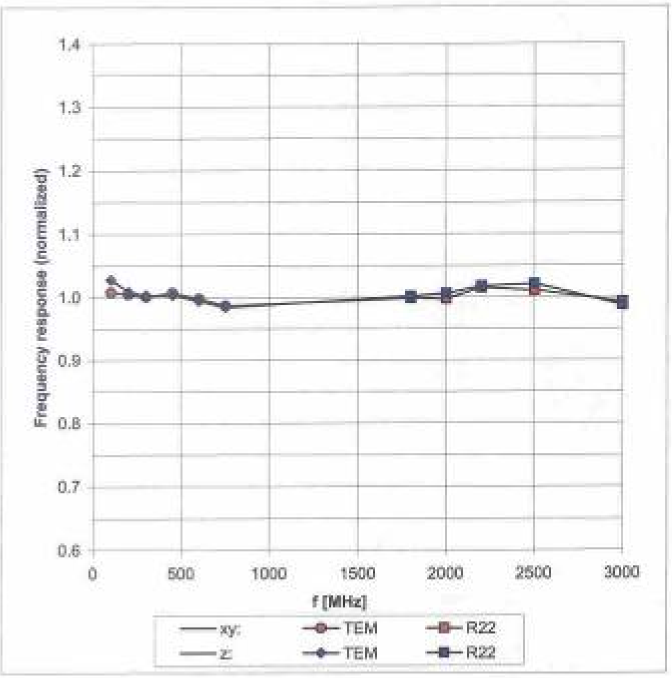
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[1] numerical linearization parameter: uncertainty not required

H3DV6 SN:6260 October 20, 2009

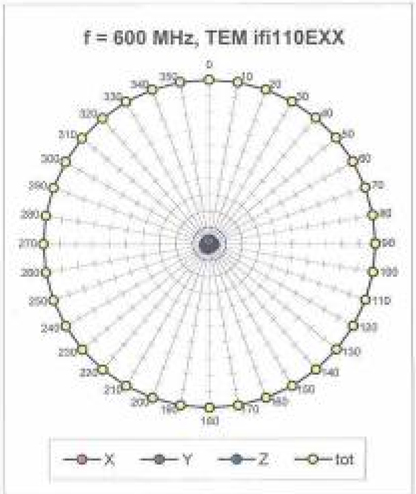
Frequency Response of H-Field

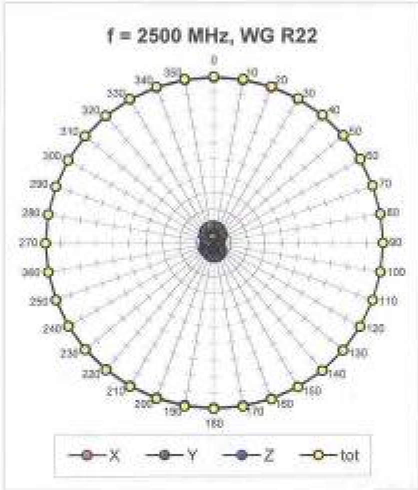
(TEM-Cell:ifi110 EXX, Waveguide R22)



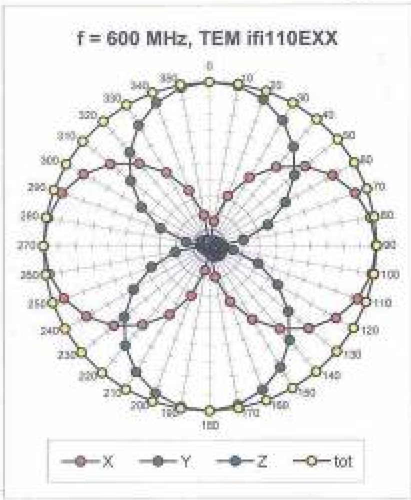
Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

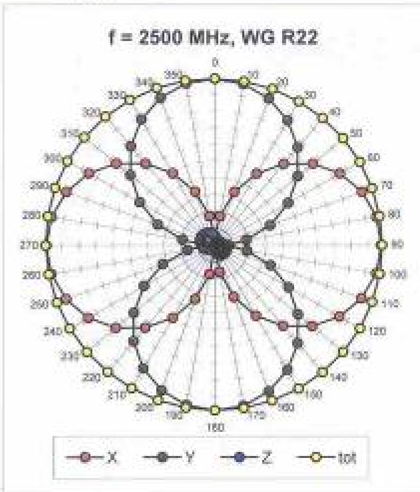
Receiving Pattern (ϕ), ϑ = 90°





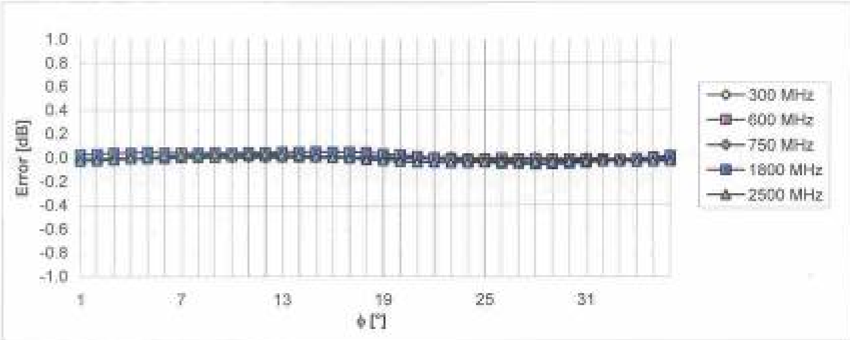
Receiving Pattern (ϕ), ϑ = 0°





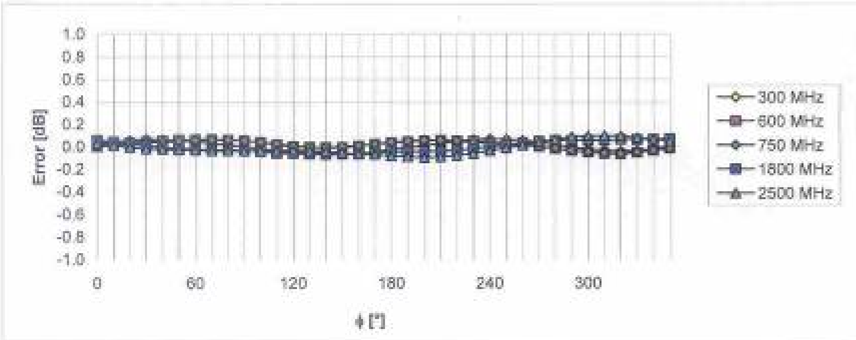
H3DV6 SN:6260 October 20, 2009

Receiving Pattern (ϕ), ϑ = 90°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), ϑ = 0°

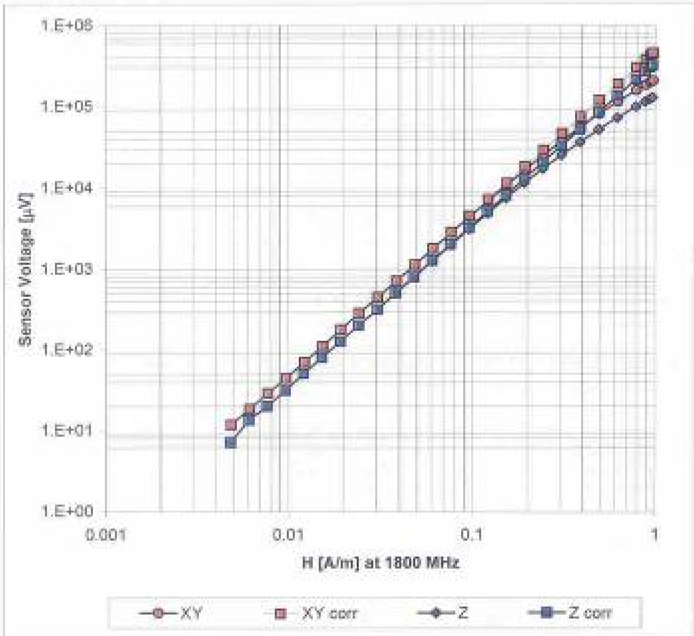


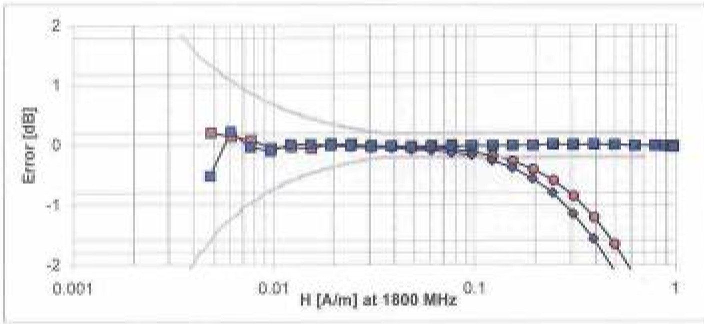
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

H3DV6 SN:6260 October 20, 2009

Dynamic Range f(H-field)

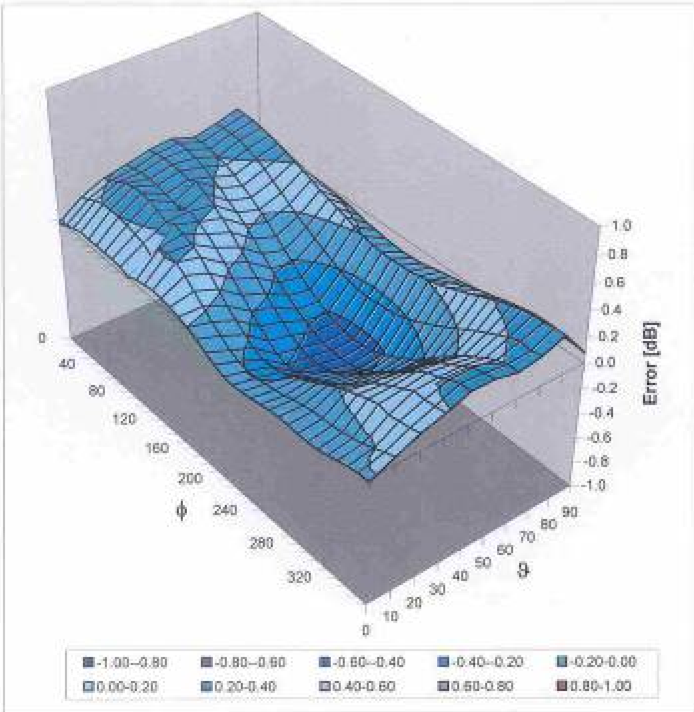
(Waveguide R22, f = 1800 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Deviation from Isotropy in Air
Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

H3DV6 SN:6260 October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-154.1
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6.0 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

ANNEX E: CD835V3 Dipole Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TA Technology (Auden)**

Certificate No: **CD835V3-1133_Apr09**

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1133
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	April 22, 2009
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	22-Dec-08 (No. ER3-2336_Dec08)	Dec-09
Probe H3DV6	SN: 6065	22-Dec-08 (No. H3-6065_-Dec08)	Dec-09
DAE4	SN: 781	20-Feb-09 (No. DAE4-781_Feb09)	Feb-10

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter R&S NRP	SN: 101748	23-Sep-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100711	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100712	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	03-Nov-04 (in house check Oct-07)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Mike Meili	Laboratory Technician	
Approved by:	Fin Bomholt	Technical Director	

Issued: April 24, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD835V3-1133_Apr09 Page 1 of 6

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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

References

[1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY4 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E- field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY4	V4.7 B80
DASY PP Version	SEMCAD	V1.8 B186
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	**835 MHz** ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW forward power	**0.446 A/m**

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end-	100 mW forward power	158.2 V/m
Maximum measured above low end	100 mW forward power	157.3 V/m
Averaged maximum above arm	100 mW forward power	**157.8 V/m**

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.2 dB	(43.3 – j12.9) Ohm
835 MHz	**33.2 dB**	**(49.3 + j2.1) Ohm**
900 MHz	17.4 dB	(53.5 – j13.6) Ohm
950 MHz	20.0 dB	(44.3 + j7.5) Ohm
960 MHz	14.8 dB	(53.2 + j18.8) Ohm

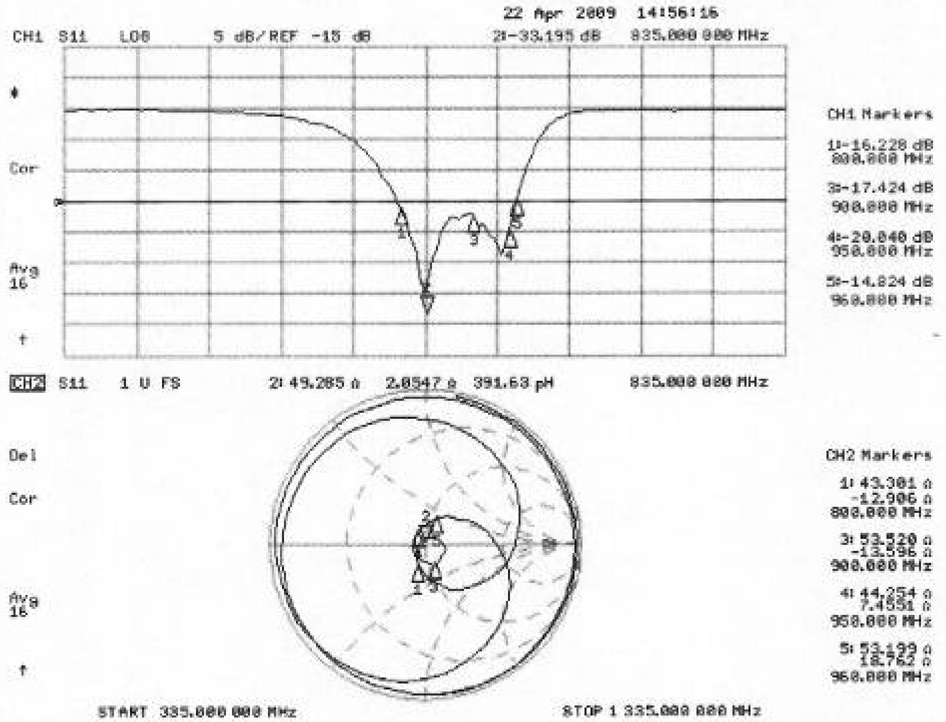
3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-field Result

Date/Time: 21.04.2009 13:38:21

Test Laboratory: SPEAG Lab 2

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1133
Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY4 (High Precision Assessment)

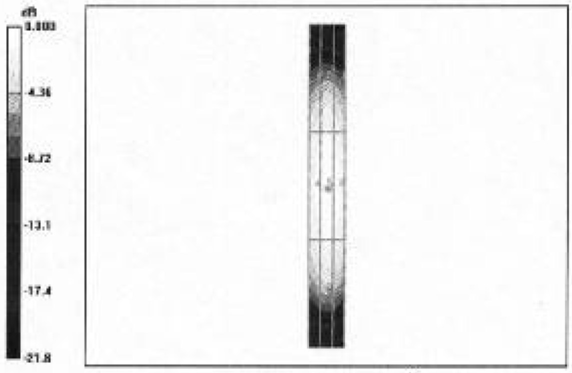
DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.446 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.472 A/m; Power Drift = -0.006 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.364 M4**	Grid 2 **0.385 M4**	Grid 3 **0.368 M4**
Grid 4 **0.417 M4**	Grid 5 **0.446 M4**	Grid 6 **0.426 M4**
Grid 7 **0.365 M4**	Grid 8 **0.393 M4**	Grid 9 **0.376 M4**



0 dB = 0.446A/m

3.3.3 DASY4 E-field Result

Date/Time: 22.04.2009 12:51:53

Test Laboratory: SPEAG Lab 2

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1133
Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY4 (High Precision Assessment)

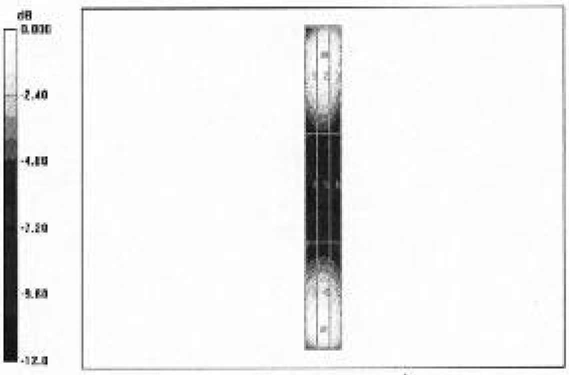
DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 158.2 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 105.8 V/m; Power Drift = -0.013 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **152.4 M4**	Grid 2 **158.2 M4**	Grid 3 **154.6 M4**
Grid 4 **84.6 M4**	Grid 5 **86.9 M4**	Grid 6 **84.2 M4**
Grid 7 **151.7 M4**	Grid 8 **157.3 M4**	Grid 9 **152.4 M4**



0 dB = 158.2V/m

ANNEX F: CD1880V3 Dipole Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client TA Technology (Auden)

Certificate No: CD1880V3-1115_Apr09

CALIBRATION CERTIFICATE

Object	CD1880V3 - SN: 1115
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	April 22, 2009
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	22-Dec-08 (No. ER3-2336_Dec08)	Dec-09
Probe H3DV6	SN: 6065	22-Dec-08 (No. H3-6065_-Dec08)	Dec-09
DAE4	SN 781	20-Feb-09 (No. DAE4-781_Feb09)	Feb-10

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter R&S NRP	SN: 101748	23-Sep-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100711	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100712	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	22-Nov-04 (in house check Oct-07)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Mike Meili	Laboratory Technician	
Approved by:	Fin Bomholt	Technical Director	F. Bomholt

Issued: April 24, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

References

[1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY4 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E- field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

1. **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY4	V4.7 B80
DASY PP Version	SEMCAD	V1.8 B186
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	**1880 MHz** ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2. **Maximum Field values**

H-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured	100 mW forward power	**0.468 A/m**

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW forward power	140.5 V/m
Maximum measured above low end	100 mW forward power	138.2 V/m
Averaged maximum above arm	100 mW forward power	**139.4 V/m**

Uncertainty for E-field measurement: 12.8% (k=2)

3. **Appendix**

3.1 Antenna Parameters

Frequency	**Return Loss**	**Impedance**
1710 MHz	24.0 dB	(52.4 + j6.0) Ohm
1880 MHz	**21.4 dB**	**(46.8 + j7.6) Ohm**
1900 MHz	22.4 dB	(48.1 + j7.2) Ohm
1950 MHz	30.1 dB	(50.1 + j3.1) Ohm
2000 MHz	18.4 dB	(40.5 + j5.4) Ohm

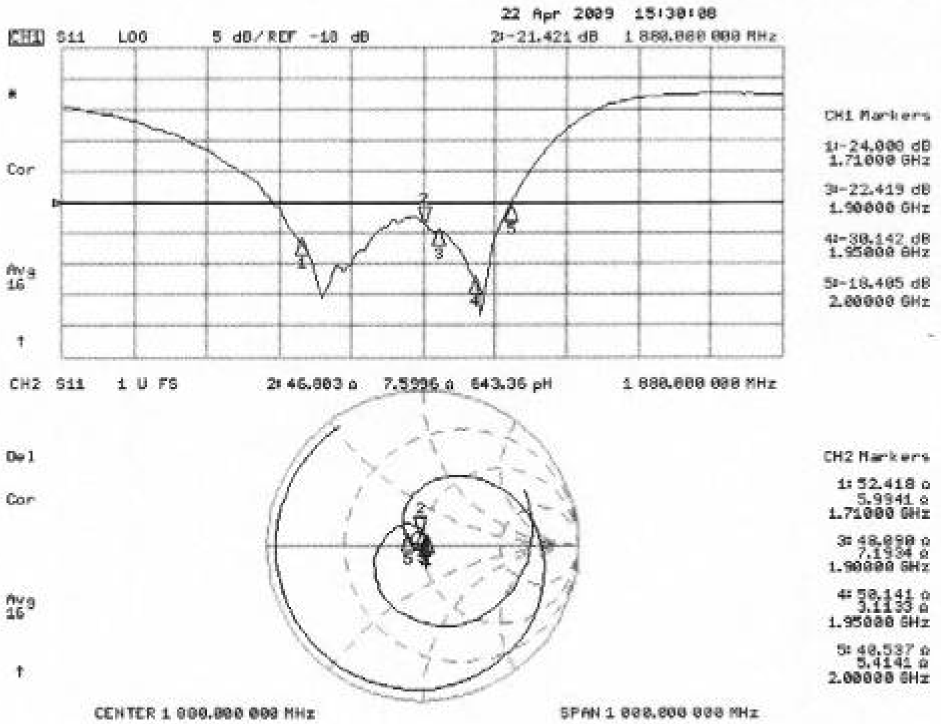
3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-Field Result

Date/Time: 21.04.2009 16:14:56

Test Laboratory: SPEAG Lab 2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1115
Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY4 (High Precision Assessment)

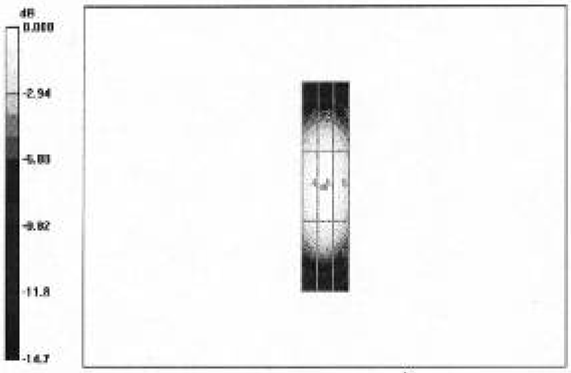
DASY4 Configuration:

- Probe: H3DV6 - SN6065; Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.468 A/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.497 A/m; Power Drift = -0.028 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.410 M2**	Grid 2 **0.428 M2**	Grid 3 **0.405 M2**
Grid 4 **0.448 M2**	Grid 5 **0.468 M2**	Grid 6 **0.442 M2**
Grid 7 **0.409 M2**	Grid 8 **0.430 M2**	Grid 9 **0.403 M2**



0 dB = 0.468A/m

3.3.3 DASY4 E-Field Result

Date/Time: 22.04.2009 15:33:14

Test Laboratory: SPEAG Lab 2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1115
Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY4 (High Precision Assessment)

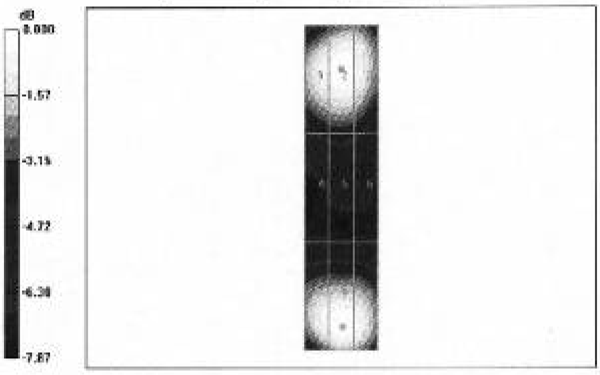
DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 140.5 V/m
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 157.9 V/m; Power Drift = 0.005 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **133.8 M2**	Grid 2 **138.2 M2**	Grid 3 **134.2 M2**
Grid 4 **90.3 M3**	Grid 5 **92.5 M3**	Grid 6 **88.2 M3**
Grid 7 **132.9 M2**	Grid 8 **140.5 M2**	Grid 9 **137.0 M2**



0 dB = 140.5V/m

ANNEX G: DAE4 Calibration Certificate

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client TA – SH (Auden)

Certificate No: DAE4-871_Nov10

CALIBRATION CERTIFICATE

Object: DAE4 - SD 000 D04 BJ - SN: 871

Calibration procedure(s): QA CAL-06.v22
Calibration procedure for the data acquisition electronics (DAE)

Calibration date: November 18, 2010

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Keithley Multimeter Type 2001	SN: 0810278	28-Sep-10 (No:10376)	Sep-11
Secondary Standards	**ID #**	**Check Date (in house)**	**Scheduled Check**
Calibrator Box V1.1	SE UMS 006 AB 1004	07-Jun-10 (in house check)	In house check: Jun-11

	Name	Function	Signature
Calibrated by:	Andrea Guntli	Technician	
Approved by:	Fin Bomholt	R&D Director	

Issued: November 18, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: DAE4-871_Nov10 Page 1 of 5

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Glossary

DAE	data acquisition electronics
Connector angle	information used in DASY system to align probe sensor X to the robot coordinate system.

Methods Applied and Interpretation of Parameters

- *DC Voltage Measurement:* Calibration Factor assessed for use in DASY system by comparison with a calibrated instrument traceable to national standards. The figure given corresponds to the full scale range of the voltmeter in the respective range.
- *Connector angle*: The angle of the connector is assessed measuring the angle mechanically by a tool inserted. Uncertainty is not required.
- The following parameters as documented in the Appendix contain technical information as a result from the performance test and require no uncertainty.
  - *DC Voltage Measurement Linearity:* Verification of the Linearity at +10% and -10% of the nominal calibration voltage. Influence of offset voltage is included in this measurement.
  - *Common mode sensitivity:* Influence of a positive or negative common mode voltage on the differential measurement.
  - *Channel separation:* Influence of a voltage on the neighbor channels not subject to an input voltage.
  - *AD Converter Values with inputs shorted:* Values on the internal AD converter corresponding to zero input voltage
  - *Input Offset Measurement*: Output voltage and statistical results over a large number of zero voltage measurements.
  - *Input Offset Current:* Typical value for information; Maximum channel input offset current, not considering the input resistance.
  - *Input resistance:* Typical value for information: DAE input resistance at the connector, during internal auto-zeroing and during measurement.
  - *Low Battery Alarm Voltage:* Typical value for information. Below this voltage, a battery alarm signal is generated.
  - *Power consumption:* Typical value for information. Supply currents in various operating modes.

DC Voltage Measurement

A/D - Converter Resolution nominal
High Range: 1LSB = 6.1μV , full range = -100...+300 mV
Low Range: 1LSB = 61nV , full range = -1.......+3mV
DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Calibration Factors	X	Y	Z
High Range	404.757 ± 0.1% (k=2)	404.740 ± 0.1% (k=2)	405.181 ± 0.1% (k=2)
Low Range	3.98219 ± 0.7% (k=2)	3.93489 ± 0.7% (k=2)	3.96831 ± 0.7% (k=2)

Connector Angle

Connector Angle to be used in DASY system	90.0 ° ± 1 °

Appendix

1. DC Voltage Linearity

High Range		Reading (μV)	Difference (μV)	Error (%)
Channel X	+ Input	200001.2	-1.56	-0.00
Channel X	+ Input	20000.71	0.71	0.00
Channel X	- Input	-19997.87	1.63	-0.01
Channel Y	+ Input	199994.3	1.99	0.00
Channel Y	+ Input	19998.92	-1.08	-0.01
Channel Y	- Input	-20000.26	-0.76	0.00
Channel Z	+ Input	200009.2	-1.04	-0.00
Channel Z	+ Input	19998.70	-1.10	-0.01
Channel Z	- Input	-20000.16	-0.76	0.00

Low Range		Reading (μV)	Difference (μV)	Error (%)
Channel X	+ Input	2000.1	0.16	0.01
Channel X	+ Input	199.58	-0.52	-0.26
Channel X	- Input	-200.79	-0.89	0.45
Channel Y	+ Input	1999.9	-0.03	-0.00
Channel Y	+ Input	199.45	-0.55	-0.27
Channel Y	- Input	-200.31	-0.41	0.21
Channel Z	+ Input	2000.1	0.33	0.02
Channel Z	+ Input	199.13	-0.77	-0.38
Channel Z	- Input	-201.47	-1.37	0.69

2. Common mode sensitivity

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Common mode Input Voltage (mV)	High Range Average Reading (μV)	Low Range Average Reading (μV)
Channel X	200	14.25	12.86
	- 200	-12.68	-14.21
Channel Y	200	-10.04	-10.39
	- 200	9.20	9.17
Channel Z	200	-0.85	-1.40
	- 200	-0.34	-0.31

3. Channel separation

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Input Voltage (mV)	Channel X (μV)	Channel Y (μV)	Channel Z (μV)
Channel X	200	-	2.85	0.69
Channel Y	200	2.41	-	2.73
Channel Z	200	2.54	0.73	-

4. AD-Converter Values with inputs shorted

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	High Range (LSB)	Low Range (LSB)
Channel X	15920	15517
Channel Y	16171	16732
Channel Z	15803	16474

5. Input Offset Measurement

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec
Input 10MΩ

	Average (μV)	min. Offset (μV)	max. Offset (μV)	Std. Deviation (μV)
Channel X	0.03	-2.35	0.86	0.43
Channel Y	-0.50	-1.49	0.49	0.38
Channel Z	-0.92	-2.21	0.14	0.44

6. Input Offset Current

Nominal Input circuitry offset current on all channels: <25fA

7. Input Resistance (Typical values for information)

	Zeroing (kOhm)	Measuring (MOhm)
Channel X	200	200
Channel Y	200	200
Channel Z	200	200

8. Low Battery Alarm Voltage (Typical values for information)

Typical values	Alarm Level (VDC)
Supply (+ Vcc)	+7.9
Supply (- Vcc)	-7.6

9. Power Consumption (Typical values for information)

Typical values	Switched off (mA)	Stand by (mA)	Transmitting (mA)
Supply (+ Vcc)	+0.01	+6	+14
Supply (- Vcc)	-0.01	-8	-9

ANNEX H: The EUT Appearances and Test Configuration

Picture 1: Constituents of EUT

Picture 2: Test Setup